

## Pockels Cells (EO Q-switches)



### The Electro-Optic Effect

The linear electro-optic effect, also known as the Pockels effect, describes the variation of the refractive index of an optical medium under the influence of an external electrical field. In this case certain crystals become birefringent in the direction of the optical axis which is isotropic without an applied voltage.

When linearly polarized light propagates along the direction of the optical axis of the crystal, its state of polarization remains unchanged as long as no voltage is applied. When a voltage is applied, the light exits the crystal in a state of polarization which is in general elliptical.

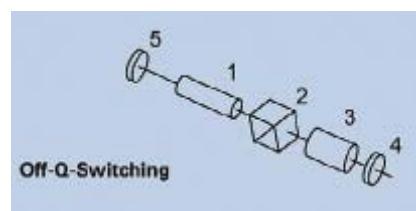
In this way phase plates can be realized in analogy to conventional polarization optics. Phase plates introduce a phase shift between the ordinary and the extraordinary beam. Unlike conventional optics, the magnitude of the phase shift can be adjusted with an externally applied voltage and a  $\lambda/4$  or  $\lambda/2$  retardation can be achieved at a given wavelength. This presupposes that the plane of polarization of the incident light bisects the right angle between the axes which have been electrically induced. In the longitudinal Pockels effect the direction of the light beam is parallel to the direction of the electric field. In the transverse Pockels cell they are perpendicular to each other. The most common application of the Pockels cell is the switching of the quality factor of a laser cavity.

### Q-Switching

Laser activity begins when the threshold condition is met: the optical amplification for one round trip in the laser resonator is greater than the losses (output coupling, diffraction, absorption, scattering). The laser continues emitting until either the stored energy is exhausted, or the input from the pump source stops. Only a fraction of the storage capacity is effectively used in the operating mode. If it were possible to block the laser action long enough to store a maximum energy, then this energy could be released in a very short time period.

A method to accomplish this is called Q-switching. The resonator quality, which represents a measure of the losses in the resonator, is kept low until the maximum energy is stored. A rapid increase of the resonator quality then takes the laser high above threshold, and the stored energy can be released in a very short time. The resonator quality can be controlled as a function of time in a number of ways. In particular, deep modulation of the resonator quality is possible with components that influence the state of polarization of the light. Rotating the polarization plane of linearly polarized light by  $90^\circ$ , the light can be guided out of the laser at a polarizer. The modulation depth, apart from the homogeneity of the  $90^\circ$  rotation, is only determined by the degree of extinction of the polarizer.

The linear electro-optical (Pockels) effect plays a predominant role besides the linear magneto-optical (Faraday) and the quadratic electro-optical (Kerr) effect. Typical electro-optic Q-switches operate in a so called  $\lambda/4$  mode.



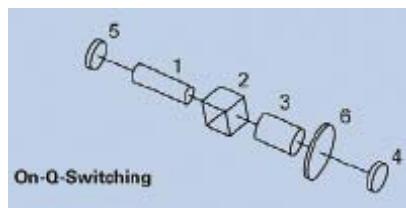
#### a) Off Q-Switching

Light emitted by the laser rod (1) is linearly polarized by the polarizer (2). If a  $\lambda/4$  voltage is applied to

the Pockels cell (3), then on exit, the light is circularly polarized. After reflection from the resonator mirror (4) and a further passage through the Pockels cell, the light is once again polarized, but the plane of polarization has been rotated by 90°. The light is deflected out of the resonator at the polarizer, but the resonator quality is low and the laser does not start to oscillate. At the moment the maximum storage capacity of the active medium has been reached, the voltage of the Pockels cell is turned off very rapidly; the resonator quality increases immediately and a very short laser pulse is emitted. The use of a polarizer can be omitted for active materials which show polarization dependent amplification (eg. Nd:YAlO<sub>3</sub>, Alexandrite, Ruby, etc.).

### b) On Q-Switching

Unlike off Q-switching, a  $\lambda/4$  plate (6) is used between the Pockels cell (3) and the resonator mirror (4). If no voltage is applied to the Pockels cell the laser resonator is blocked: no laser action takes place. A voltage pulse opens the resonator and permits the emission of laser light.



### Pulse Picking

Typically Femto-Second-Lasers emit pulses with a repetition rate of several 10MHz. However many applications like regenerative amplifying require slower repetition rates. Here a Pockels cell can be used as an optical switch: by applying ultra fast and precisely timed  $\lambda/2$ -voltage pulses on the Pockels cell, the polarization of the Laser light can be controlled pulse wise. Thus, combined with a polarizer the Pockels cell works as an optical gate.

### Selection Criteria

The selection of the correct Q-switch for a given application is determined by the excitation of the laser; the required pulse parameters, the switching voltage, the switching speed of the Pockels cell, the wavelength, polarization state and degree of coherence of the light.

### Type of Excitation

Basically, both off and on Q-switching are equivalent in physical terms for both cw and for pulse pumped lasers. On Q-switching is, however, recommended in cw operation because a high voltage pulse and not a rapid high voltage switch-off is necessary to generate a laser pulse. This method also extends the life time of the cell. Over a long period of time, the continuous application of a high voltage would lead to electrochemical degradation effects in the KD\*P crystal. We advice the use of an on Q-switching driver. Off Q-switching is more advantageous for lasers stimulated with flash lamps because the  $\lambda/4$  plate is not required. In order to prevent the electrochemical degradation of the KD\*P crystal in the off Q-switching mode we recommend a trigger scheme in which the high voltage is turned off between the flashlamp pulses and turned on to close the laser cavity before the onset of the pump pulse. The cell CPC and SPC series are recommended for diode pumped solid state lasers. These cells are ultra compact and will operate in a short length resonator: this is necessary to achieve very short laser pulses.

### Pulse Parameters

The series LM n, LM n IM, and LM n SG cells are recommended for lasers with a power density of up to 500MW/cm<sup>2</sup>. The LM n and LM n SG cells are used for lasers with very high amplification. The SG cells with sol-gel technology have the same transmission as the immersion cells and both are typically used when a higher transmission is required. At high pulse energies LMx cells are preferred.

Brewster Pockels cells are recommended for lasers with low amplification, such as Alexandrite lasers. The passive resonator losses are minimal due to a high transmission of 99%.

The CPC and SPC series cells are suitable for small, compact lasers and especially for OEM applications. They are available as dry cells and immersion cells.

The level of deuterium content in an electro-optic crystal influences the spectral position of the infrared edge. The higher the deuterium level the further the absorption edge is shifted into the infrared spectral region: for Nd:YAG at 1064nm, the laser absorption decreases. Crystals, which are deuterated to >98%, are available for lasers with a high repetition rate or a high average output power.

### Pockels Cell Switching Voltage

Using double Pockels cells can half the switching voltage. This is achieved by switching two crystals electrically in parallel and optically in series. The damage threshold is very high and the cells are mainly

used outside the resonator.

### **Electro Optic Material**

The selection of the electro-optic material depends on its transmission range. Further on the Laser parameters and the application as well have to be taken into account.

For wavelengths from  $0.25\mu\text{m}$  to  $1.1\mu\text{m}$ , longitudinal Pockels cells made of KD\*P and a deuterium content of 95% should be considered. If the deuterium content is higher the absorption edge of the material is shifted further into the infrared. KD\*P crystal cells with a deuterium content >98% can be used up to  $1.3\mu\text{m}$ .

KD\*P can be grown with high optical uniformity and is therefore recommended for large apertures. The spectral window of BBO also ranges from  $0.25\mu\text{m}$  to  $1.3\mu\text{m}$ , but besides BBO also provides a low dielectric constant and a high damage threshold. Therefore BBO is recommended for Lasers with high repetition rate and high average powers. RTP, with an optical bandwidth from  $0.5\mu\text{m}$  up to  $1.5\mu\text{m}$  combines low switching voltage and high laser induced damage threshold. Together with its relative insensitivity for Piezo effects RTP is best suited for precise switching in high repetition rate lasers with super fast voltage drivers.

For wavelengths from  $1.5\mu\text{m}$  up to  $3\mu\text{m}$  we recommend LiNbO<sub>3</sub>.

### **Suppression of Piezo Effects**

Like any other insulating material electro optical crystals show Piezo effects when high voltage is applied. The extend of the Piezo ringing depends on the electro optic material and usually its effect on the extinction ratio is negligible when used for Q-switching. However for pulse picking applications, which require highly precise switching behaviour, we offer specially Piezo damped Pockels cells which suppress these ringing effects efficiently.

### **State of Polarization**

The MIQS and CIQS series cells are supplied with an integrated polarizer: the alignment of the Pockels cell relative to the polarizer thus becomes unnecessary. The rotational position of the cell relative to the resonator axis can be chosen at will. However, should the polarization state of the light in the resonator be determined by other components, such as anisotropic amplification of the laser crystal or Brewster surfaces of the laser rod, then the rotational position of the cell will be determined by these factors. Thin film polarizers are used and the substrate is mounted at the Brewster angle. A parallel beam displacement of 1mm results from this configuration and can be compensated by adjusting the resonator.

## Pockels Cell (EO Q-switch, Electro-optic Q-switch)

A Pockels cell alters the polarization state of light passing through it when an applied voltage induces birefringence changes in an electro-optic crystal such as KD\*P and BBO. When used in conjunction with polarizers, these cells can function as optical switches, or laser Q-switches. Frequently, Q-switches are employed in laser cavities for the purpose of shortening the output pulse, resulting in a light beam with enhanced peak intensity. In order to provide the device best suited to your purpose, we offer the industry standard QX series, economical IMPACT cells, BBO-based LightGate, and large-aperture TX Pockels cell lines. High-speed electronic drivers properly matched to the cell produce the best results for short pulse applications.

You can operate the cell with either a pull-up voltage or a pull-down voltage. Changing the polarity will only change the direction of the phase rotation. You should not, however, operate the cell with a constant applied voltage potential between the terminals, or a duty cycle greater than ~ 2%.

### 1. IMPACT Series EO Q-switches



From the world leader in nonlinear materials and electro-optic devices comes the ideal Pockels cell for OEM applications, the IMPACT. Once again, we set the industry standard - and at an exceptional price. In general, it operates below 1kHz.

The IMPACT employs the finest strain-free, highly deuterated KD\*P available. Ceramic apertures ensure robust performance in demanding applications. Ultra-high-damage threshold Sol Gel and dielectric AR coatings are offered for a variety of laser wavelengths. The standard pin-type connectors (superior for high-voltage applications) provide quick connections and simplified design and assembly. Conventional threaded connectors are available as an option. The IMPACT is back-filled with dry nitrogen.

#### Applications:

- OEM laser systems
- Medical/cosmetic lasers
- Versatile R&D laser platforms
- Military & aerospace laser systems

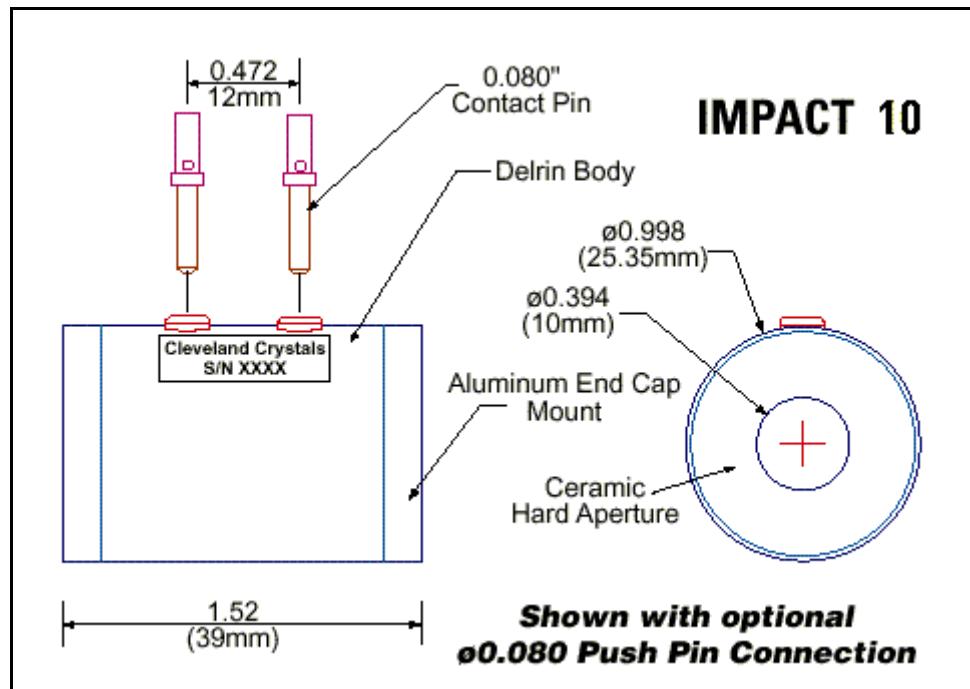
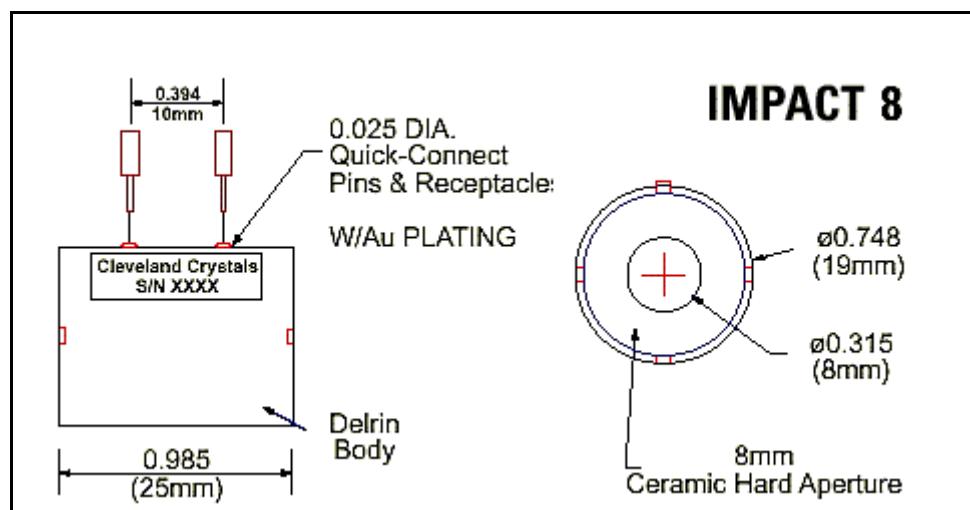
FEATURES	BENEFITS
CCI Quality - economically priced	Exceptional value
Finest strain-free KD*P	High contrast ratio High damage threshold Low 1/2 wave voltage
Single pass optical transmission	>98%
Space efficient	Ideal for compact lasers
Ceramic apertures	Clean and highly damage-resistant
High contrast ratio	Exceptional hold-off
Quick electrical connectors	Efficient/reliable installation
Ultra-flat crystals	Excellent beam propagation

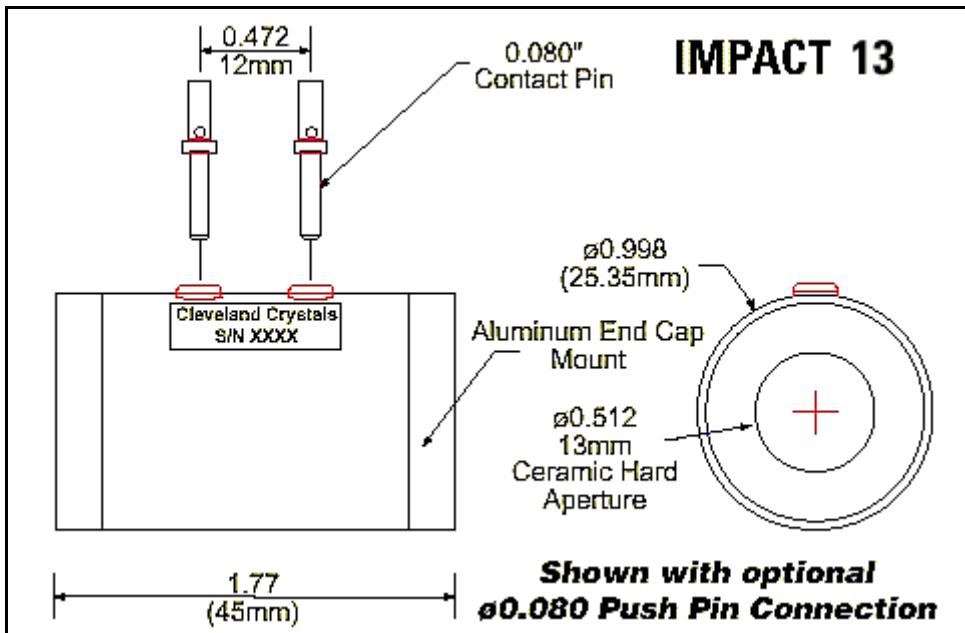
#### Remark:

- Impact 8 standard wavelength: 1064nm & 800nm
- Impact 10/13 standard wavelength: 1064nm & 755nm
- The 1/4 wave voltage for any of our KD\*P cells, @ 800nm, will be ~2.5KV, +/- 10%

**Typical Specification**

Electro-optical @ 1064nm			
1/4 Wave Voltage: 3.3 kV			
Transmitted Wave Front Error : <1/8 Wave			
ICR>2000:1			
VCR>1500:1			
Capacitance: 6 pF			
Sol Gel Damage Threshold @ 1064nm, 10ns pulse: 40J/cm <sup>2</sup>			
Housing Dimensions	IMPACT 8	IMPACT 10	IMPACT 13
Aperture	8 mm	10 mm	13 mm
Length	25 mm	39 mm	45 mm
Diameter	19 mm	25.35 mm	25.35 mm





## 2. QX Series EO Q-switches

The QX series sets the standard for KD\*P electro-optic Q-switches. These devices provide reliable, stable performance for a diverse range of laser applications.

We offer a unique rebuild program that extends the QX lifetime. All rebuilt units are upgraded with the latest product improvements and are returned with a new one-year warranty.

The standard configuration employs a broad band, high damage threshold Sol Gel AR coating for improved durability and performance. The QX series is also available with index matching fluid and a choice of end caps. All units are tested for optic and electric function and are supplied with a QA inspection report.

### Features

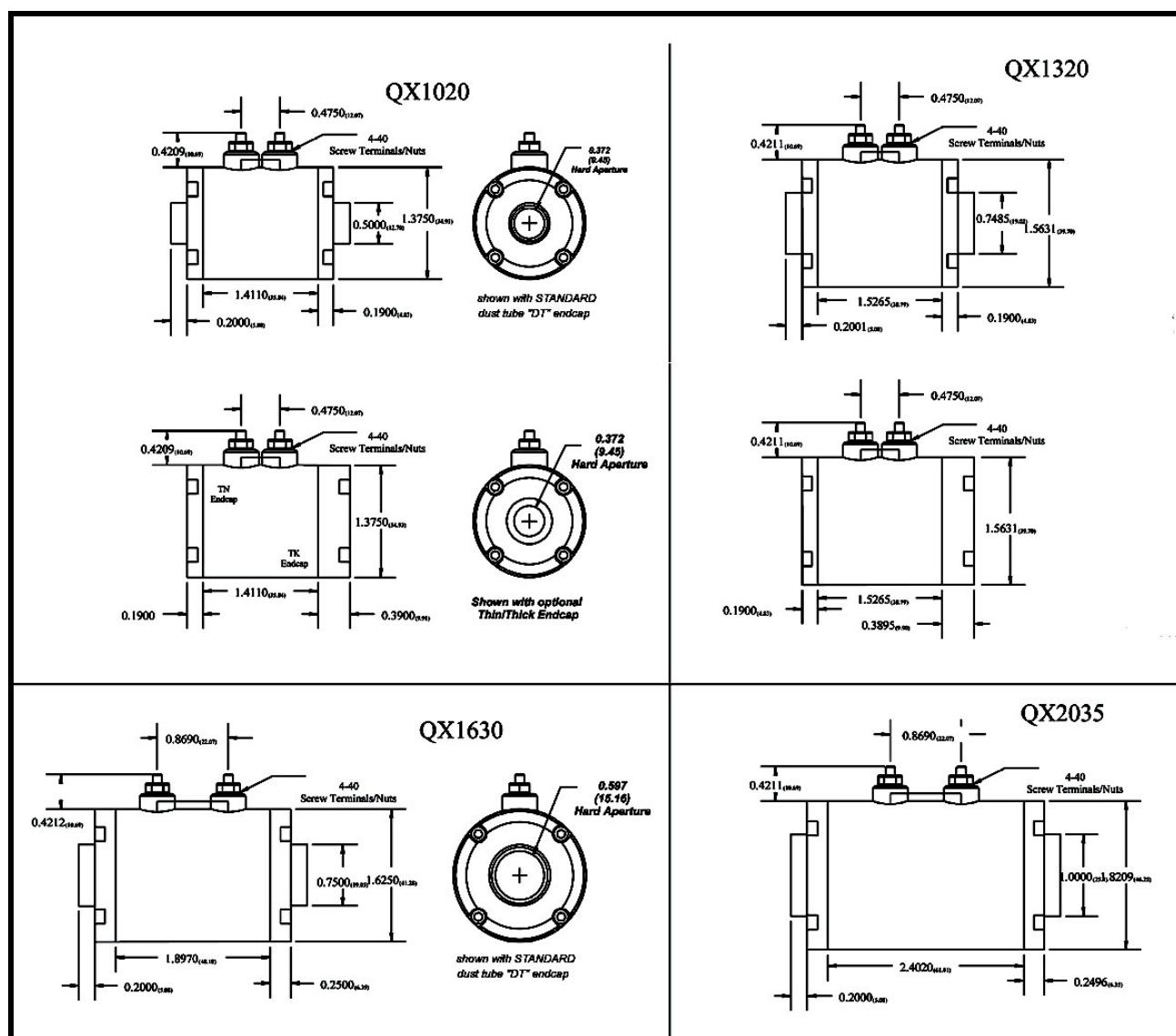
- Industry-proven performance
- Dry or fluid-filled
- Highest (99.9% KD\*P) deuterium levels in industry
- Adhesive/Epoxy-free assembly
- Premium UV-grade fused silica windows
- Apertures from 9.25mm diameter up to 19.5mm diameter
- Lowest absorption in industry
- High-reliability
- Economical upgrade/rebuild program
- Highest optical damage thresholds
- Accessible technical support
- Standard performance documentation
- One-year limited warranty
- Operation up to 10kHz (special order)



## Performa Data

Typical Specification 99% KD*P	QX1020	QX1320	QX1630	QX2035
<b>Physical</b>				
Hard aperture diameter	9.25 mm	12.3 mm	15.1 mm	19.5 mm
Single Pass Insertion Loss	<1.4%	<1.4%	<1.8%	<2.0%
<b>Voltage Contrast Ratio</b>				
(Cross polarizers)	5000:1	4000:1	3500:1	3000:1
(Parallel polarizers)	2500:1	1500:1	1800:1	1600:1
DC Quarter wave voltage @1064nm	3.2 kV	3.5 kV	3.3 kV	3.5 kV
Single Pass Distortion @ 633nm	< $\lambda/8$	< $\lambda/8$	< $\lambda/8$	< $\lambda/8$
<b>Electrical</b>				
Capacitance @ 1 kHz	6pF	9pF	9pF	13pF
10-90% Rise time (50Ω line)	0.8 ns	1.1 ns	1.1 ns	1.5 ns

Note: Specifications are subject to change without notice.



### 3. LiNbO<sub>3</sub> Pockels Cells

- LiNbO<sub>3</sub>-based Pockels cell
- Preferably for Er:YAG-, Ho:YAG-, Tm:YAG laser
- For wavelengths up to 3μm
- Brewster cells BPZ 5 IR for laser with low amplification
- Compact design

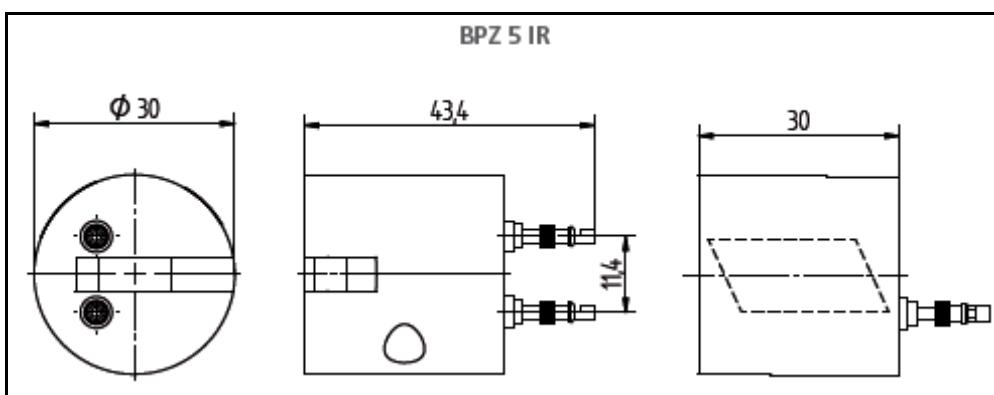
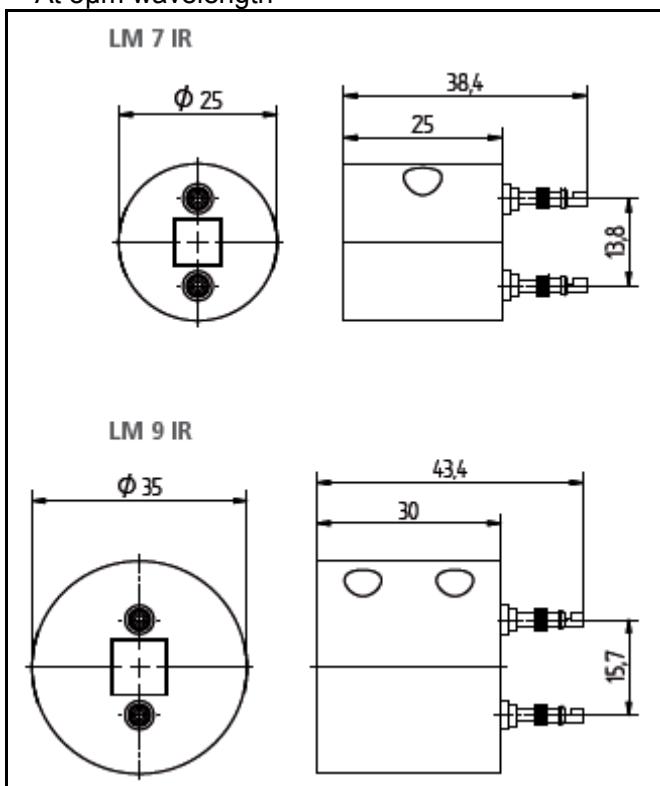
- Wave front deformation: <  $\lambda/4$
- Damage threshold: > 100MW/cm<sup>2</sup> at 1064nm, 10ns, 1Hz (typical, not guaranteed)

Please state the applied wavelength when ordering.

Order No.	Product	Clear Aperture (mm)	Transmission typical (%)	Extinction ratio (voltage-free)	$\lambda/4$ voltage
8450-3030-001	LM 7 IR <sup>1)</sup>	7,45 x 7,45	98	> 100:1	3 kV
8450-3032-001	LM 9 IR <sup>1)</sup>	9 x 9	98	> 100:1	3 kV
8450-3036-000	BPZ 5 IR <sup>1)</sup>	5 x 5	99	> 100:1	3 kV
8450-3038-000	BPZ 5 IR <sup>2)</sup>	5 x 5	99	> 100:1	3 kV

<sup>1)</sup> At 2μm wavelength

<sup>2)</sup> At 3μm wavelength



#### 4. LightGate Series BBO Pockels Cell

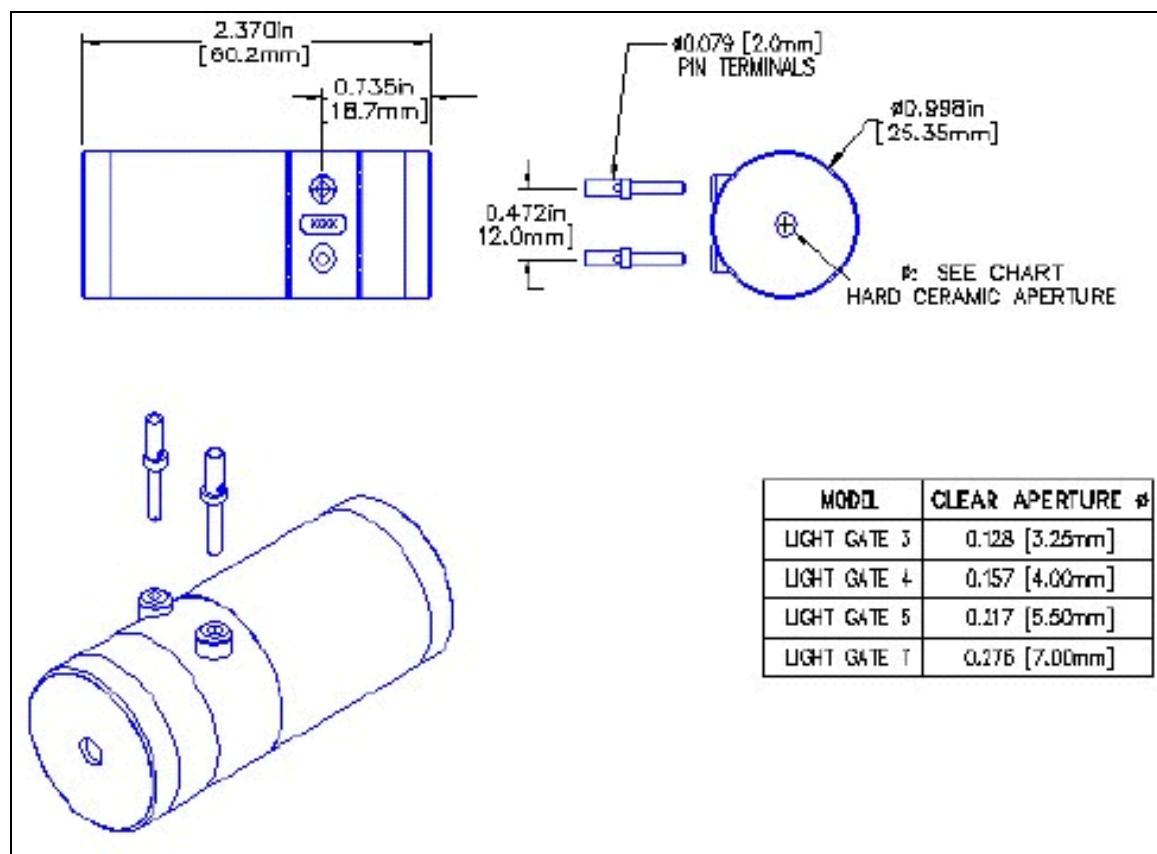
LightGate BBO Pockels cells are the preferred alternative to KD\*P Pockels cells for high-average power and high repetition rate applications. The LightGate series BBO Pockels cell employs dual crystal geometry to minimize drive voltage (~3.4kV quarter-wave voltage @ 1064nm for 4mm aperture LightGate 4). BBO is transparent from approximately 0.2 to 2.1mm and is not subject to tracking degradation. It also shows low piezoelectric ringing, which is useful for repetition rates of hundreds of kilohertz. LightGate Pockels cells are useful for regenerative amplifiers and in high pulse repetition rate micro-machining lasers and high-average power lasers for material processing and metal annealing. We also offer special single crystal cells, extra-long, reduced voltage cells and cells attenuated for ultra-low ringing, for special applications.



##### Features:

- High Repetition Rate as high as 1MHz
- Low Acoustic Noise
- Damage Resistant Ceramic Apertures
- High Average Power Applications
- Compact design
- Q-switch and Regen-amp Applications

ICR	>2500:1
VCR	>500:1
Apertures	3.25mm, 4mm, 5.5mm & 7mm
Spectral range of operation	~200-2100nm (must specify single wavelength of operation)
Single Pass Optical Transmission	>98%
DC quarter-wave Voltage	2.8KV, 3.4KV, 4.4KV & 5.4KV
Capacitance	4pF (all)
Transmitted Wavefront Error	< λ/6



## 5. BBO Pockels Cells

- BBO-based Pockels cell
- Suited for Q-switch applications with high repetition rates
- Wave front deformation: <  $\lambda/4$
- Damage threshold: > 300MW/cm<sup>2</sup> at 1064nm, 10ns, 1Hz (typical, not guaranteed)
- Optionally available with integrated Brewster polarizer: BBPC n BP
- Optionally available with integrated  $\lambda/4$  disk: BBPC n WP
- Optionally available with Piezo attenuator: BBPC n pp

Please state the applied wavelength when ordering.

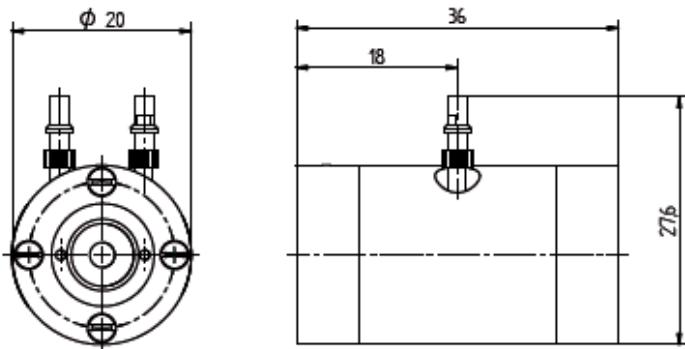
Product Number	Wavelength (nm) <sup>1)</sup>	Clear Aperture (mm)	Transmission typical (%)	Extinction ratio (voltage-free)	$\lambda/4$ voltage <sup>2)</sup>	Capacity (pF)
BBPC 3	1064	$\varnothing$ 2.8	98	> 1000:1	3.6 KV	4
BBPC 4	1064	$\varnothing$ 3.6	98	> 1000:1	4.8 KV	4
BBPC 5	1064	$\varnothing$ 4.6	98	> 1000:1	6.0 KV	4

<sup>1)</sup> other wavelength available upon request.

<sup>2)</sup> DC at 1064nm

### DDBBPC 4 Pockels Cell at 355nm

- BBO crystal: AR/AR coated at 355 nm
- Clear aperture: 3.6 mm
- Transmission: > 98 %
- Extinction ratio without voltage applied: > 500:1
- I/2 voltage at 355 nm: approx. 1.6 KV
- Wavefront distortion at 633 nm: I/4
- Windows: wedged, AR/AR at 355 nm



## 6. IRX Series CdTe Pockels Cell

Initially designed to address the Q-switched CO<sub>2</sub> laser market at 10.6μm, the cadmium telluride - based IRX Q-switch may be configured to operate from 3-12μm. Its' high electro-optic coefficient and non-hygroscopic nature makes CdTe well-suited for this purpose. Through more than 30 years of electro-optic device design experience, we provide IRX Pockels cells with application-specific AR coatings or Brewster-cut ends, in apertures ranging from 3mm-10mm. The IRX Pockels cells are able to address applications beyond the spectral range of traditional oxide Pockels cells.



ICR	>500:1 @ 10.6μm
Apertures	3mm, 5mm, 7mm & 4 x 10mm*
Spectral range of operation	3-12μm (must specify single wavelength of operation)
Optical transmission	>98% at 10.6μm (other wavelengths available)
DC half-wave Voltage(for nominal 5mm aperture x 50mm length)	~ 5kV** @ 10.6μm

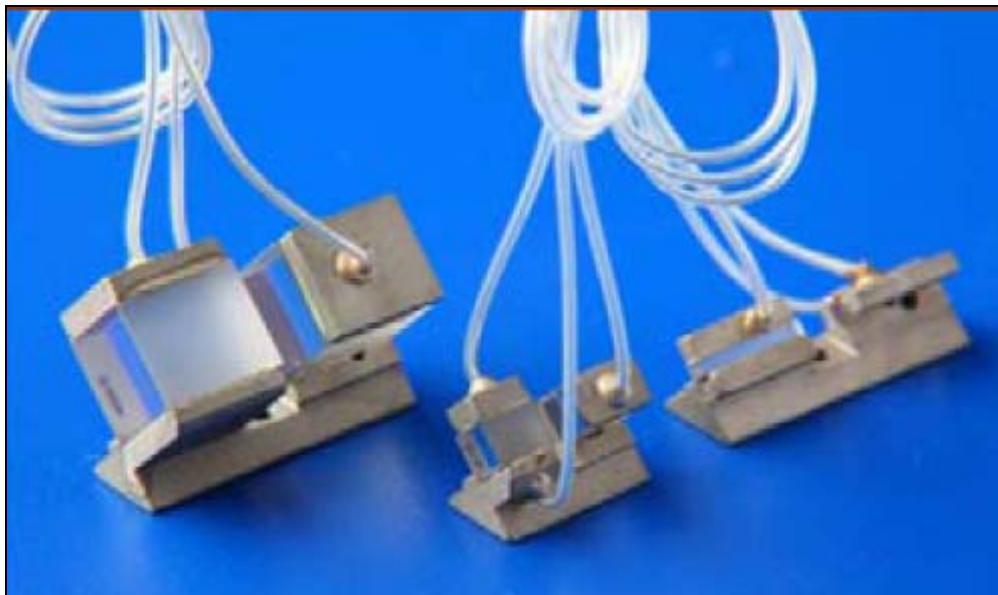
\* Custom aperture sizes available

\*\* Voltage is a function of electrode spacing and crystal length and will vary with application. Voltage shown is for the 4x10mm configuration.

## 7. RTP Electro-optic Q-Switch

RTP (Rubidium Titanyl Phosphate) is a robust electro - optic crystal suitable for a wide variety of applications (such as Q - Switches, Amplitude & Phase Modulators, Pulse Pickers, etc.) and operation in industrial, medical, and defense products. The crystal is transparent at most common visible and near infrared laser wavelengths. It performs well over a wide temperature range (from - 500C to +700C)

and at high repetition rates. RTP based Q - switch devices are offered in matched pair configurations, in a temperature compensating design. When used for applications such as Q-switches and Amplitude Modulators, the crystals are mounted such that the input beam is polarized along the diagonal of the face. Our Q-switch is built using 2 RTP (Rubidium Titanyl Phosphate) elements in a temperature compensating design. The unique properties of RTP, including high electrical resistivity ( $\sim 10^{12} \Omega\text{-cm}$ ) and a high damage threshold, result in a Q-switch with excellent properties.



#### **Advantages:**

- High Damage Threshold: No Piezoelectric Ringing
- Low Insertion Loss: Thermal Compensating Design
- Non-hygroscopic

#### **Specifications:**

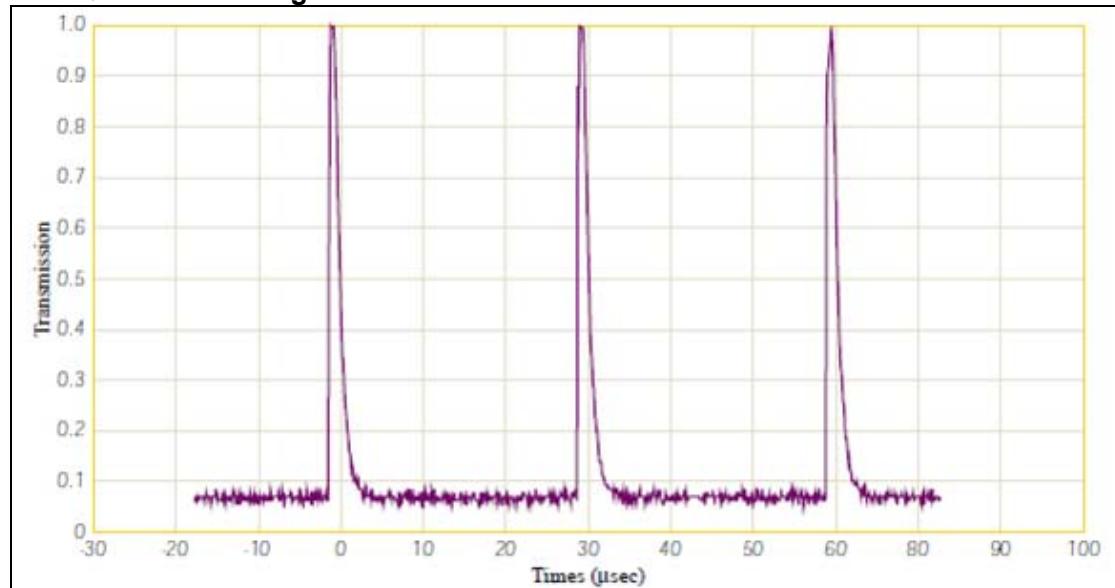
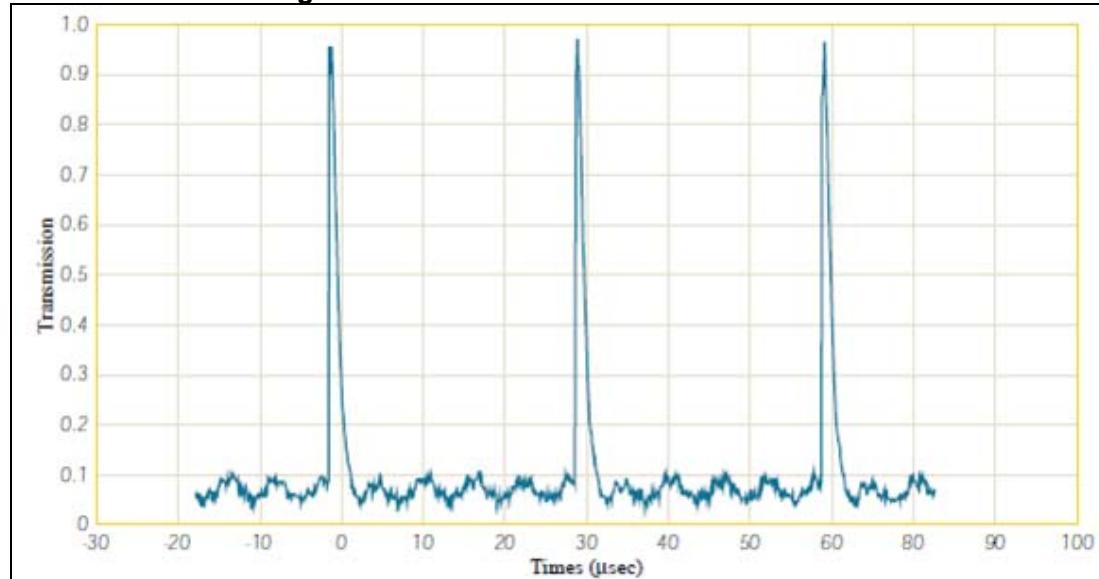
- Transmission at 1064 nm: > 98.5 %
- Half Wave Voltage at 1064 nm, for 9x9x25 nm Q switch: 1.3 - 1.5 KV
- Contrast Ratio: > 20 dB
- Clear Aperture: From 2x2 to 15x15 mm
- Acceptance Angle: > 1 degree
- AR coatings: R < 0.2% at 1064 nm
- Damage threshold: > 600 MW/cm<sup>2</sup> at 1064 nm ( $\tau=10$  ns)

#### **Part Numbers: STR-O-CR-L-E-W**

STR means RTP EO Q-switches, O means the crystal's cutting orientation (X/Y/Z), CR means cross section, L means crystal length, E means extinction ratio in dB (20, 23, 25 or 30), W means wavelength.

#### **Selection Guide**

Part number	Crystal size (mm)	HWV (kV)	Part number	Crystal size (mm)	HWV (kV)
STR-Y-020-5-20-1064	2x2x5	1.3	STR-Y-020-10-20-1064	2x2x10	0.66
STR-Y-030-5-20-1064	3x3x5	2.0	STR-Y-030-10-20-1064	3x3x10	0.99
STR-Y-040-5-20-1064	4x4x5	2.6	STR-Y-040-10-20-1064	4x4x10	1.3
STR-Y-050-5-20-1064	5x5x5	3.3	STR-Y-050-10-20-1064	5x5x10	1.7
STR-Y-060-5-20-1064	6x6x5	4.0	STR-Y-060-10-20-1064	6x6x10	2.0
STR-X-020-5-20-1064	2x2x5	1.6	STR-X-020-10-20-1064	2x2x10	0.79
STR-X-030-5-20-1064	3x3x5	2.4	STR-X-030-10-20-1064	3x3x10	1.2
STR-X-040-5-20-1064	4x4x5	3.2	STR-X-040-10-20-1064	4x4x10	1.6
STR-X-050-5-20-1064	5x5x5	4.0	STR-X-050-10-20-1064	5x5x10	2.0
STR-X-060-5-20-1064	6x6x5	4.8	STR-X-060-10-20-1064	6x6x10	2.4
STR-X-070-5-20-1064	7x7x5	5.6	STR-X-070-10-20-1064	7x7x10	2.8
STR-X-080-5-20-1064	8x8x5	6.4	STR-X-080-10-20-1064	8x8x10	3.2
STR-X-090-5-20-1064	9x9x5	7.2	STR-X-090-10-20-1064	9x9x10	3.6

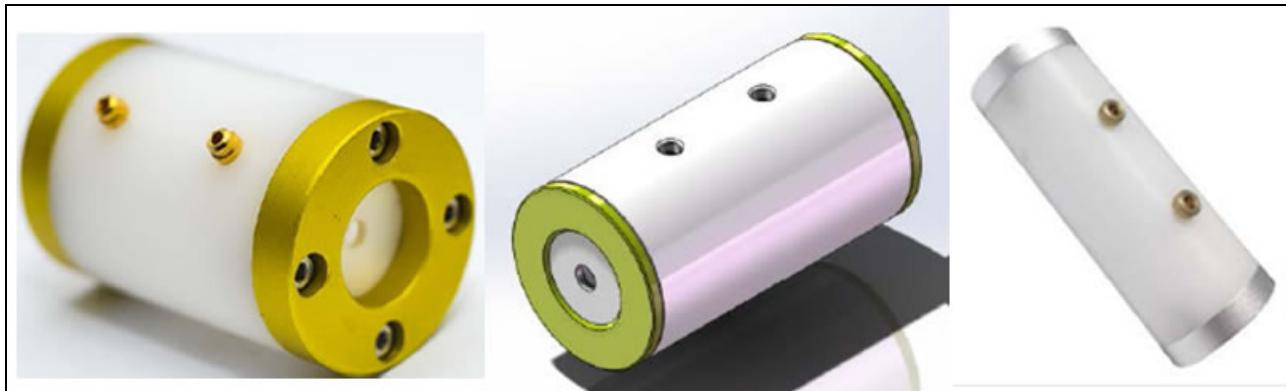
**RTP Q-switch working at 30kHz**

**BBO Q-switch working at 30kHz**


The graphs above show the behaviour of RTP and BBO Q switches at high repetition rates. In particular, the BBO shows Piezoelectric ringing at 30 kHz, while the RTP Q switch shows no ringing at this frequency. The BBO Q switch has a 2.5x2.5x25 mm element, while the RTP Q switch has two 6x6x7mm elements.

# STC Series Pockels Cells (Acousto-optic Q-switches)

## 1. STC Series BBO Pockels Cells

- Minimal piezoelectric ringing
- Low absorption
- Broad transmission ranges from 200nm to 2000nm
- Compact size



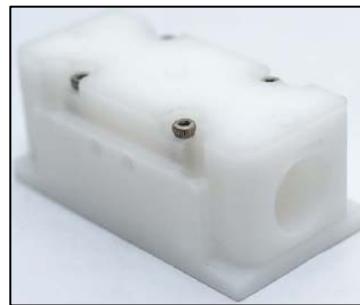
Part Number	STC-BBO1.8	STC-BBO2.5	STC-BBO3.6	STC-BBO2.8
Dimensions	25.4×39	25.4×39	25.4×39	20X37.5
Clear Aperture	1.8	2.5	3.6	2.8
Crystal Size	2*2*20	3*3*20	4*4*20	3X3X20
Quantity of Crystals	1	1	1	1
Wavelength range	410-3500nm	410-3500nm	410-3500nm	410-3500nm
Quarter-Wave Voltage	2400	3600	4800	3600
Operation Wavelength	1064nm	1064nm	1064nm	1064NM
Electrodes	Gold-coated PIN	Gold-coated PIN	Gold-coated PIN	Gold-coated PIN
Insertion Loss	<2%	<2%	<2%	<2%
Extinction Ratio	>1000:1	>1000:1	>1000:1	>1000:1
Capacitance	>4	>4	>4	>4
LIDT@1064nm, 10ns 10Hz	500MW/cm <sup>2</sup>	500MW/cm <sup>2</sup>	500MW/cm <sup>2</sup>	>600MW/cm <sup>2</sup>

Part Number	STC-2BBO1.8	STC-2BBO2.5	STC-2BBO3.6
Dimensions	25.4×67	25.4×67	25.4×67
Clear Aperture	1.8	2.5	3.6
Crystal Size	2*2*20	3*3*20	4*4*20
Quantity of Crystals	2	2	2
Wavelength range	410-3500nm	410-3500nm	410-3500nm
Quarter-Wave Voltage	1200	1800	2400
Operation Wavelength	1064nm	1064nm	1064nm
Electrodes	Gold-coated PIN	Gold-coated PIN	Gold-coated PIN
Insertion Loss	<2%	<2%	<2%
Extinction Ratio	>500:1	>500:1	>500:1
Capacitance	>4	>4	>4
LIDT@1064nm, 10ns 10Hz	500MW/cm <sup>2</sup>	500MW/cm <sup>2</sup>	500MW/cm <sup>2</sup>

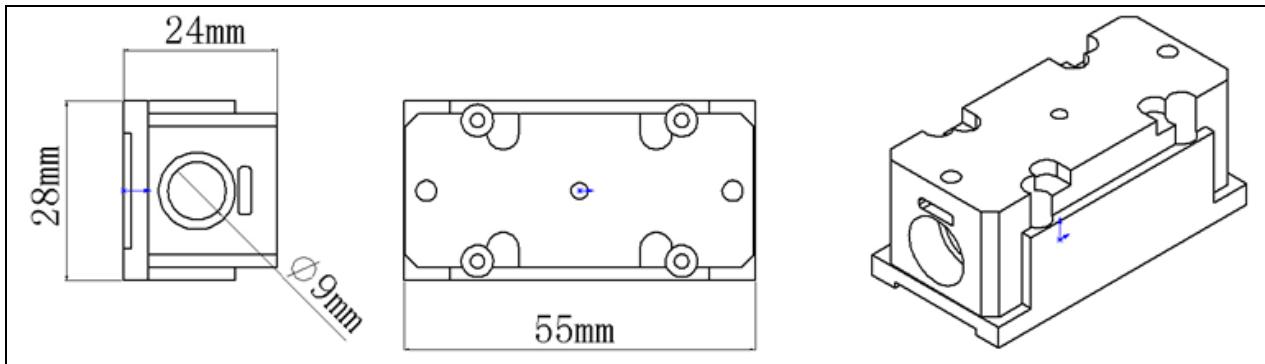
## 2. STC Series LiNbO<sub>3</sub> Pockels Cells

Our optical grade LiNbO<sub>3</sub> crystal has good electro-optic performance, large nonlinear coefficient, good optical uniformity, stable mechanical and chemical properties, no deliquescent, low half-wave voltage, and can be applied to high repetition rate operation. It is high in extinction ratio and laser damage threshold. LN electro-optic Q-switches are widely used in Er:YAG, Ho:YAG, Tm:YAG lasers, and are suitable for low-power Q-switched output, especially in laser ranging. We offer the most compact Q-switches for our customers. Furthermore, we also can custom-design and make the Q-switches according to your specific requirements to meet your various applications.

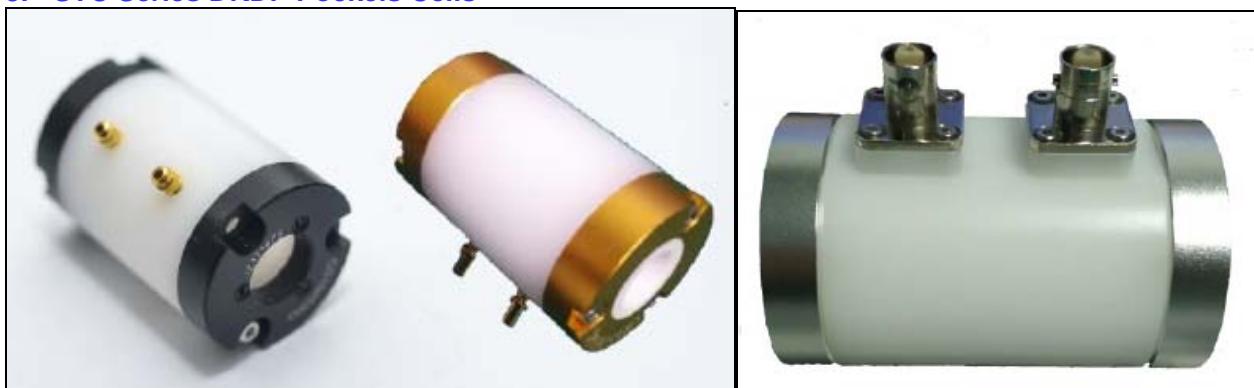
- Large nonlinear optical coefficient
- Large receiving angle
- Small walk-off angle
- Wide temperature and spectral bandwidth
- High photoelectric coefficient and low dielectric constant
- Non-absorbent, stable chemical and mechanical properties



Part Number	STC-LN2.5	STC-LN5	STC-LN8	STC-LN9
Dimensions	55x28x24	55x28x24	55x28x24	55x28x24
Clear Aperture	2.5	5	8	9
Crystal Size	3*3*25	5*5*25	8*8*25	9X9X25
Quantity of Crystals	1	1	1	1
Wavefront Distortion	$\lambda /8$ @633nm	$\lambda /8$ @633nm	$\lambda /8$ @633nm	$\lambda /8$ @633nm
Quarter-Wave Voltage	885	1400	2400	2700
Operation Wavelength	1064nm	1064nm	1064nm	1064nm
Electrodes	Cu/Cr PIN	Cu/Cr PIN	Cu/Cr PIN	Cu/Cr PIN
Insertion Loss	<3%	<3%	<3%	<3%
Extinction Ratio	>500:1	>500:1	>500:1	>500:1
Capacitance	>5	>5	>5	>5
LIDT@1064nm, 10ns 10Hz	300MW/cm <sup>2</sup>	300MW/cm <sup>2</sup>	300MW/cm <sup>2</sup>	>300MW/cm <sup>2</sup>



### 3. STC Series DKDP Pockels Cells



DKDP electro-optic Q-switches (Q-switch, Pockels Cells) are widely used in high-power, narrow-pulse (<10ns) laser systems due to their unique physical properties and excellent optical quality.

The DKDP crystal is a uniaxial crystal with excellent optical quality with an extinction ratio of >2000:1 (measured using a 632 nm He-Ne laser) with a wave front distortion of 98%. The DKDP electro-optic Q-switching capacitance is small (about 3-5pF), so that the rise time is short (<0.5ns), and a narrow pulse width laser beam can be achieved during Q-switching. Compared with the widely used electro-optic crystals on the market, DKDP crystals have higher damage thresholds (>1GW/cm<sup>2</sup>) under optical conditions of 10ns pulse width, 1064 nm wavelength and repetition rate 10Hz.

- Wave front distortion: low capacitance
- Short rise time: ~3pF

- High transmittance: >98%
- High damage threshold: >1GW/cm<sup>2</sup>
- No static birefringence, no photorefractive damage
- Anti-reflective coated quartz window
- Resistant to ambient temperature shock and excellent electro-optic performance

Part Number	STC-DK10	STC-DK12	STC-DK25	STC-DK30	STC-DK50
Dimension	D25x39mm	D25x39mm	D55X80	D55X80	NIL
Clear Aperture	10mm	12mm	25mm	30mm	50mm
Quarter-wave Voltage	3200V	3200V	6500V	6800V	7500V
Electrodes	PIN	PIN	Cu/Cr	Cu/Cr	Cu/Cr
Insertion Loss	<2%	<2%	<2%	<3%	<5%
Extinction Ratio	>2500:1	>2500:1	>155:1	>1000:1	>700:1
Capacitance	<5 pF	<5 pF	<12pF	<15pF	<35pF
LIDT @1064nm, 10ns, 10Hz	>800MW/cm2	>800MW/cm2	>850MW/cm2; >1GW/cm2 @500ps	>850MW/cm2; >1GW/cm2 @500ps	>850MW/cm2; >1GW/cm2 @500ps

We can custom-design and –make specific Q-switches such as cubic outlook, nitrogen encapsulated, lead-wire electrodes etc. Please send us your detailed requirements via email or phone.



# STEK Series Pockels Cells

## 1. STEK-series KTP Pockels Cells

New STEK-PCK series KTP Pockels are based on specially grown high resistivity KTP crystals. KTP crystals have better optical homogeneity and higher damage threshold comparing to RTP crystals. The outstanding feature is a possibility to operate KTP Pockels cells at high duty cycles or even to keep at high voltage for the longer time.

### Applications:

- Q-switching for high repetition rate lasers 1 kHz – 1 MHz
- Pulse picking of high repetition rate lasers

### Features:

- More than twice smaller HV requirement comparing to double BBO Pockels cells
- Operates at high duty cycles
- Very low piezo-electric resonances
- Standard available apertures: 4x4, 6x6 and 8x8 mm



Model	STEK-PCK4	STEK-PCK4-O
Clear aperture diameter, mm		3.5
Crystal size (WxHxL), mm		4x4x10
Quantity of crystals		2
Half-wave voltage (@ 1064 nm), kV DC		<1.8
Capacitance, pF		4
Optical transmission, %		>98
Contrast ratio		>1:500
Cell size, mm	Ø25.4x42.2	25x11.1x7.5

Model	STEK-PCK6	STEK-PCK6-O
Clear aperture diameter, mm		5.5
Crystal size (WxHxL), mm		6x6x10
Quantity of crystals		2
Half-wave voltage (@ 1064 nm), kV DC		<2.5
Capacitance, pF		<6
Optical transmission, %		>98
Contrast ratio		>1:500
Cell size, mm	Ø25.4x42.2	25x13.8x10.6

## 2. STEK-series KD\*P Pockels Cells

Pockels cells are used to change the polarization state of light passing through it when a voltage is applied to the electrodes of electro-optic crystals such as KD\*P. When used in conjunction with polarizer, Pockels cells can be used as fast optical switches. Typical applications include Q-switching of the laser cavity, laser cavity dumping and coupling light into and from regenerative amplifiers. KD\*P based Pockels cells are routinely used for Q-switching applications from the 400 nm to about 1.1 µm. Most of commercial flashlamp pumped Nd:YAG lasers and low repetition rate DPSS Nd:YAG lasers are

equipped with KD\*P based Pockels cell for laser cavity Q-switching. Electro-optical KD\*P crystals have high laser power resistant dielectric AR coatings. Additionally STE-PC12SR and STEK-D-compact series Pockels cells have AR coated windows for improved lifetime and protection in less user friendly environment.

- Economically priced
- Compact size
- Low absorption
- Transmission from 400 to 1100 nm

**Applications:**

- Q-switching of the laser cavity
- Cavity Dumping



Model	STEK-PC5S	STEK-PC5D	STEK-PC10S	STEK-D-Compact/ 9	STEK-D-Compact/12
Clear aperture, mm	4.5x4.5	4.5x4.5	9.5x9.5	Ø8	Ø11
Crystal size, (WxHxL)mm	5x5x16	5x5x16	10x10x25	Ø9x20	Ø12x24
Quantity of crystals	1	2	1	1	1
λ/2 voltage 1064nm, kV DC	<6.5	<3.4	<6.8	<6.8	<6.8
Capacitance, pF	1.5	3	4	6	6
Optical transmission, %	>97	>97	>97	>97	>97
Contrast ratio <sup>1)</sup>	> 1:2000	>1:1000	>1:2000	>1:2000	>1:2000
Cell size, mm	18x14x25	23x16x52	22x18x33	Ø25.4x35	Ø25.4x39

<sup>1)</sup> Measured by crossed polarizers method

Crystals are coated AR/AR@1064 nm. Other antireflection coatings are available under request. Damage threshold >5 J/cm<sup>2</sup> for 10 ns pulses at 1064 nm.

Model	STEK-PC12SR	STEK-PCR12SR-532	STEK-PCR12SR-694
Clear aperture, mm	Ø 11	Ø 11	Ø 11
Crystal size, (WxHxL)mm	Ø 12x24	Ø 12x24	Ø 12x24
Quantity of crystals	1	1	1
λ/2 voltage	@1064 nm <6.8 kV DC	@532 nm <3.5 kV DC	@694 nm <4.5 kV DC
Capacitance, pF	6	6	6
Optical transmission, %	>97	>96	>97
Contrast ratio <sup>1)</sup>	>1:2000	>1:2000	>1:2000
Cell size, mm	Ø 35 x 41.4	Ø 35 x 41.4	Ø 35 x 41.4

<sup>1)</sup> Measured by crossed polarizers method

### 3. STEK Series BBO Pockels Cells

Pockels cell are used to change the polarization state of light passing through it when a voltage is applied to the electrodes of electro-optic crystals such as BBO. When used in conjunction with polarizer, Pockels cells can be used as fast optical switches. Typical applications include Q-switching of the laser cavity, laser cavity dumping and coupling light into and from regenerative amplifiers.

BBO based Pockels cells can be useful at wavelengths from the UV to more than 2 μm. Low piezoelectric ringing makes these Pockels cells attractive for the control of high-power and high pulse repetition rate lasers. Fast switching electronic drivers properly matched to the cell are available for Q-

switching, cavity dumping and other applications. Pockels cells of PCB series are transverse field devices. Low electro-optical coefficient of BBO results in high operating voltages. The quarter-wave voltage is proportional to the ratio of electrode spacing and crystal length. As a result, smaller aperture devices have lower quarter-wave, however even for 2.5 mm aperture devices the quarter-wave voltage is as high as 4 kV @ 1064 nm. Double crystal design is employed to reduce required voltages and to allow operation in half-wave mode with fast switching times

#### Features:

- minimal piezoelectric ringing
- low absorption
- ceramic aperture is available
- broad transmission range from 200 nm to 2000 nm
- compact size

#### Applications:

- high repetition rate DPSS Q-switch
- high repetition rate regenerative amplifier control
- cavity dumping
- beam chopper



Model	STEK-PCB3S	STEK-PCB3D	STEK-PCB3S/25	STEK-PCB3D/25	STEK-PCB4S	STEK-PCB4D
Clear aperture diameter, mm	2.5	2.5	2.5	2.5	3.5	3.5
Crystal size (WxHxL), mm	3x3x20	3x3x20	3x3x25	3x3x25	4x4x20	4x4x20
Quantity of crystals	1	2	1	2	1	2
Quarter-wave voltage (@ 1064 nm), kV DC	<3.5	<1.8	<3.0	<1.5	<4.6	<2.3
Capacitance, pF	4	6	4	6	3	6
Optical transmission, %	>98	>98	>98	>98	>98	>98
Contrast ratio <sup>1)</sup>	>1:1000	>1:500	>1:1000	>1:500	>1:1000	>1:500
Cell size, mm	Ø25.4x37.2	Ø25.4x57.2	Ø25.4x42.2	Ø25.4x67.2	Ø25.4x37.2	Ø25.4x57.2

All crystals for the Pockels cells provided above are coated AR/AR@1064 nm. Other antireflection coatings are available under request. Damage threshold >5 J/cm<sup>2</sup> for 10 ns pulses at 1064 nm.

Model	STEK-PCB3S-1342	STEK-PCB3D-800	STEK-PCB3S-532
Clear aperture diameter, mm	2.5	2.5	2.5
Crystal size (WxHxL), mm	3x3x20	3x3x20	4x4x20
Quantity of crystals	2	1	1
Quarter-wave voltage, kV DC	<2.4	<2.6	<2.25
Wavelength, nm	1342	800	532
Capacitance, pF	4	6	4
Optical transmission, %	>98	>98	>98
Contrast ratio <sup>1)</sup>	>1:500	>1:1000	>1:1000
Cell size, mm	Ø25.4x57.2	Ø25.4x37.2	Ø25.4x37.2

<sup>1)</sup> Measured by crossed polarizers method

# EO Q-switch Drivers

## 1. STG-551 Pockels Cell Driver



The driver STG-551 is designed for use in product development, teaching and research laboratories. Housed in a compact 100x125x50 mm (5x5x2") aluminium case, the driver has a full suite of controls, indicators and remote control features. It operates from an external 24VDC source (power adapter included).

A unique feature of the driver is its differential bipolar output-reducing voltage to ground and shock hazard, an important feature in a laboratory environment. Leads to the pockels cell leave from the back of the case, keeping them away from hands at the front panel. The driver outputs are short-circuit proof. The driver is designed for reliability with low component stresses, the highest quality components and the use of US Navy derating standard.

An OEM version with the same electrical performance is available for inclusion in the laser product.

### Features:

- 4-7ns, 1.5-4.5kV, 1Hz-4.5kHz performance
- 50 ohm isolated trigger
- Front panel controls for high voltage setpoint and power
- DB-9 connector with: voltage monitor, remote setpoint, voltage on/off
- Status LEDs for power, high voltage and trigger

### Benefits

- Front panel or remote control
- Short-circuit protected output
- Easy integration of OEM version
- EM shielding enclosure

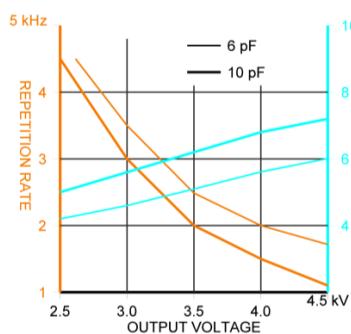
### Applications

- Ideal for development of Q-switched lasers for:
  - Medical and dermatology
  - Imaging
  - Engraving
  - Metal cutting
  - Microfabrication
  - Range finding
  - Holography

## Specifications

Parameter	Conditions	Min	Max	Units
<b>OUTPUT PULSE PARAMETERS</b>				
Pulse top	4kV output, 6pF cell capacitance		150 (nom)	ns
Delay time constant	4kV output, 6pF cell capacitance		5 (nom)	μ
Pulse voltage	Limits of adjustment	1.5	4.5	kV
Load capacitance			25	pF
<b>POWER REQUIREMENTS</b>				
24 VDC	Power limit before output fold-back		130	mA
<b>TRIGGER</b>				
Trigger voltage		2	8	V
Input Impedance		48	52	ohms
Pulse width		200		ns
Jitter, trigger to output	2ns trigger rise time, Tektronix 11801		20 (nom)	Ps RMS
<b>ENVIRONMENTAL</b>				
Temperature		-20	50	°C

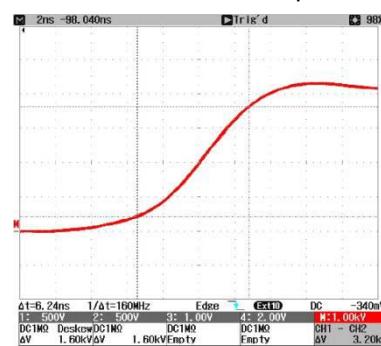
Typical performance



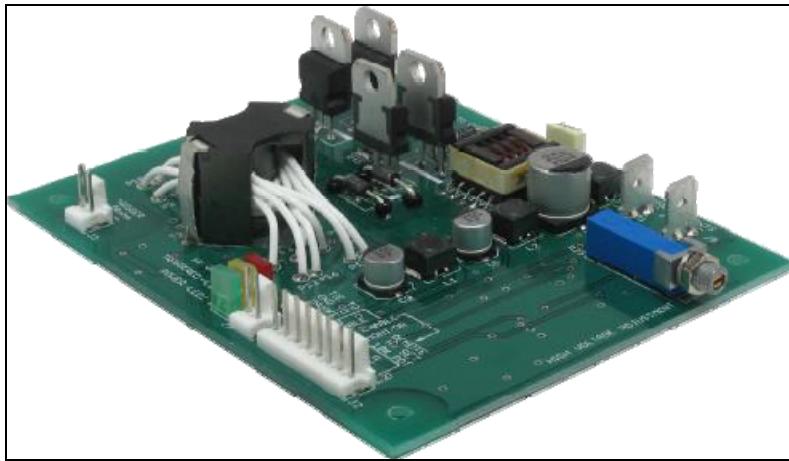
Complimentary ± output



Risetime -4kV, 10 pF



## 2. STG-551-OEM Pockels Cell Driver



The OEM driver is a cost effective, high performance Pockels cell driver for incorporation into Q-switched laser systems. The driver is packaged on a compact 100x83 mm (4x3½") circuit board. The driver is fully self-contained with the power supply and all control circuitry, needing only 24 VDC and a trigger signal to operate. Designed for reliability with low component stress and worst-case design margins, the driver meets specifications from 40C to +70C. It works with loads to 50 pF.

G&H can supply the driver in different form factors for high volume applications. For more information please see the Design-In Manual.

## Features

- 4-7 ns, 1.5-4.5 kV, 1Hz-4.5 kHz performance (see graph on following page)
- 50 ohm isolated trigger
- Voltage monitor
- Status LEDs for power, high voltage and trigger
- Remote on/off and voltage setpoint

- Bipolar balanced output
- 24 VDC input power
- Laboratory version available

### Benefits

- Low power dissipation, less heat
- Remote control ready
- Compact footprint
- Easy integration

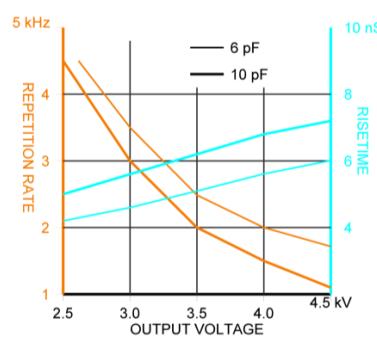
### Applications

- Medical and dermatological laser systems
- Imaging
- Engraving
- Metal cutting
- Microfabrication
- Range finding
- Holography

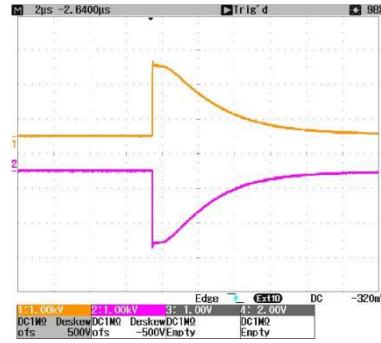
### Specifications

Parameter	Conditions	Min	Max	Units
<b>OUTPUT PULSE PARAMETERS</b>				
Pulse top	4kV output, 6pF cell capacitance		150 (nom)	ns
Delay time constant	4kV output, 6pF cell capacitance		5 (nom)	μ
Pulse voltage	Limits of adjustment	1.5	4.5	kV
Load capacitance			25	pF
<b>POWER REQUIREMENTS</b>				
24 VDC	Power limit before output fold-back		130	mA
<b>TRIGGER</b>				
Trigger voltage		2	8	V
Input Impedance		48	52	ohms
Pulse width		200		ns
Jitter, trigger to output	2ns trigger rise time, Tektronix 11801		20 (nom)	Ps RMS
<b>ENVIRONMENTAL</b>				
Temperature		-20	50	°C

Typical performance



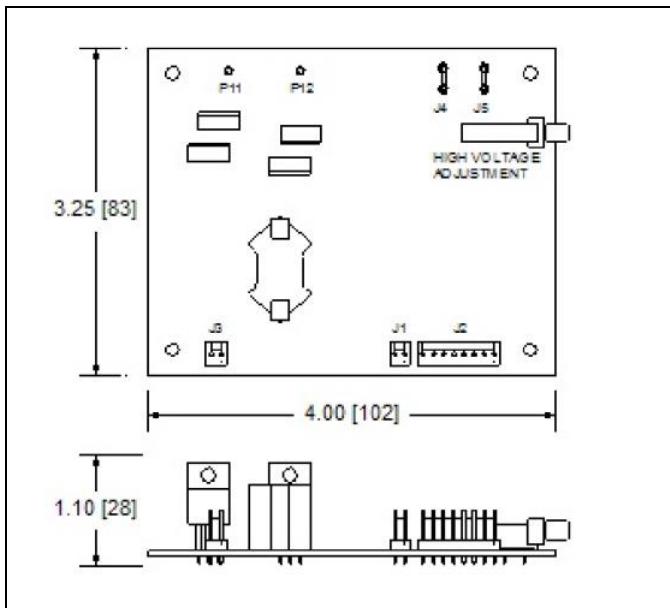
Complementary ± output



Risetime -4kV, 10 pF

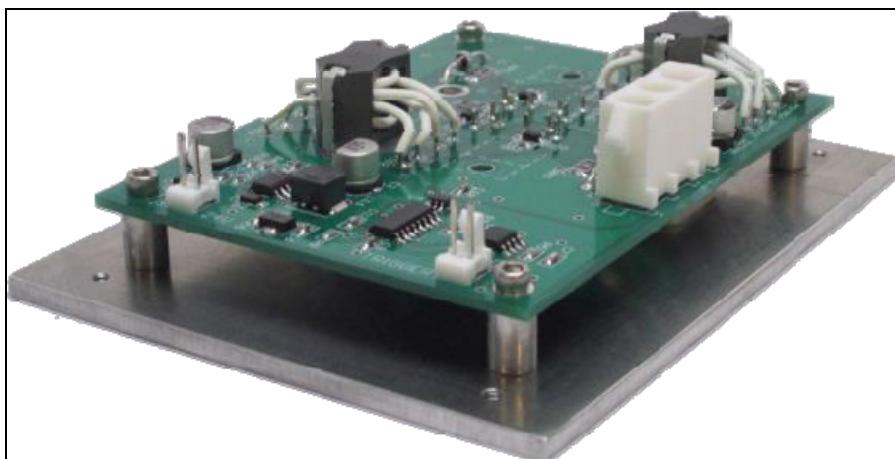


### Layout



Dimensions of the driver board.

### 3. STG-R200-OEM Pockels Cell Driver



The OEM driver is a compact OEM Pockels cell driver for inclusion in regenerative amplifiers and other pulse selection applications in solid state laser systems. The unit drives Pockels cells at 1/4 wave producing pulses at up to 2.5 kV and up to 200 kHz, with burst mode capability to 1 MHz. The driver produces a top-hat waveform with fast rising and falling edges. Heat load and space requirements are kept at a minimum due to the use of external power supplies. The trigger input is also electrically isolated from the power supplies for safety. The compact 115x90x30 mm (4.5x3.5x1.2") circuit board is supplied on an aluminium plate for convection cooling, which can also be attached to a cold plate for water cooling. The R200 can also be supplied as a turn-key integrated 19" rack system for benchtop use.

#### Key Features

- 4-7 ns rise and fall time
- 0-2.5 kV output voltage
- 0-200 kHz repetition rate
- 250 ns 3 s pulse widths
- Bipolar balanced output

#### Benefits

- Available as a turn-key system with enclosure
- High performance at a low cost
- Can be air or water cooled
- Compact footprint

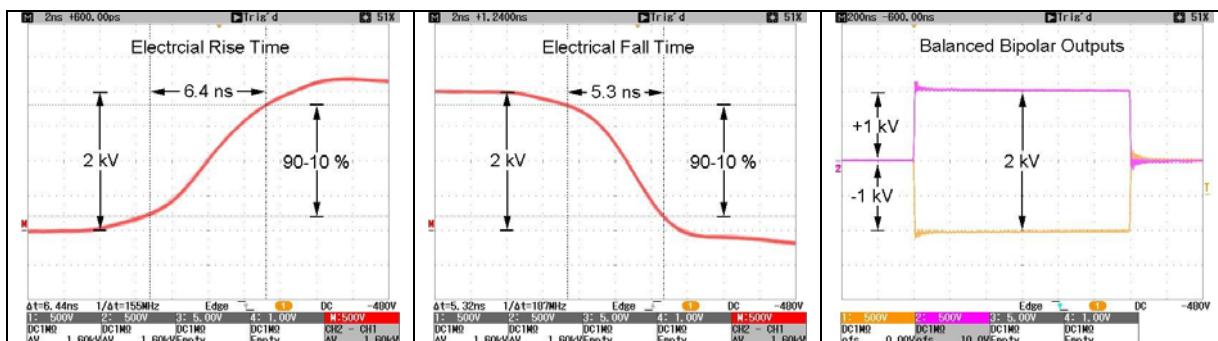
## Applications

- Metal cutting
- Welding
- Glass and sapphire cutting
- Spectroscopy

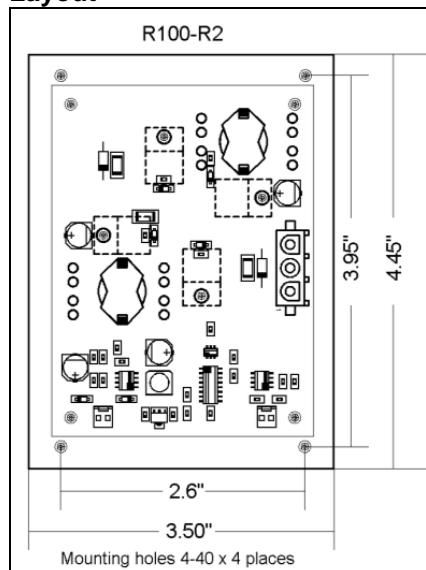
## Specifications

Parameter	Conditions	Min	Max	Units
<b>OUTPUT PULSE PARAMETERS</b>				
Pulse repetition rate	Convection cooled	0	40	kHz
	Water cooled 1.5 L/min.	40	200	kHz
Pulse voltage	External HV: ±625 VDC in for 2.5kV out	0	2.5	kV
Pulse width	Same as trigger input	250	3,000	ns
Rise, fall times	2.0 kV, 6 pF		6.0	ns
	2.0 kV, 40 pF max load		9.5	ns
<b>POWER REQUIREMENTS</b>				
Input voltage, current	24 VDC ( $\pm 2$ VDC)		200	mA
High voltage, current	2.5 kV out, ±625 VDC in, 200 kHz, 6 pF		55	mA
<b>TRIGGER</b>				
Trigger amplitude Input	Nom. 5 V, 50Ω Impedance	4	10	V
Trigger to output delay	5 V trigger		40	ns
Trigger pulse width	Sets output pulse width	250	3,000	ns
Jitter, trigger to output	2 ns trigger rise time, Tektronix 11801		20 nom	ps RMS
<b>ENVIRONMENTAL</b>				
Mounting surface*			50	°C

\*Mounting plate should be attached to a thermally conductive surface for cooling or to a cold plate for water cooling.



## Layout



### 3. STG-QDP50-OEM Pockels Cell Driver



The OEM driver is a compact OEM Pockels cell driver for inclusion in flash lamp pumped lasers. The driver is designed for Q-switching of lasers without the need for phase retardation plates. Once triggered, high voltage is applied to inhibit the laser output. After a preset delay, the Pockels cell is opened by a fast negative pulse to allow laser output, then it returns to high voltage to inhibit additional lasing.

The QDP-50 has been shown to increase Pockels cell life expectancy and laser output power relative to voltage-on scenarios often employed. It can be triggered via an SMA connector or via an optional optical input for greater noise immunity.

The compact 140x92x32 mm (5.5x3.6x1.2") circuit features an integrated high voltage power supply which includes remote voltage monitoring (1 V/kV) and remote shutdown.

#### **Key Features**

- 1.2-4.0 kV adjustable output voltage
- 0-50 Hz repetition rate
- 400 µs nominal on time (adjustable)
- 160-200 µs delayed pulse (adjustable)
- Fall time (delay pulse) less than 10 ns
- SMA trigger input standard
- Optical trigger input (optional)

#### **Benefits**

- Increased Pockels cell life
- High performance at a low cost
- Integrated high voltage power supply
- Compact footprint

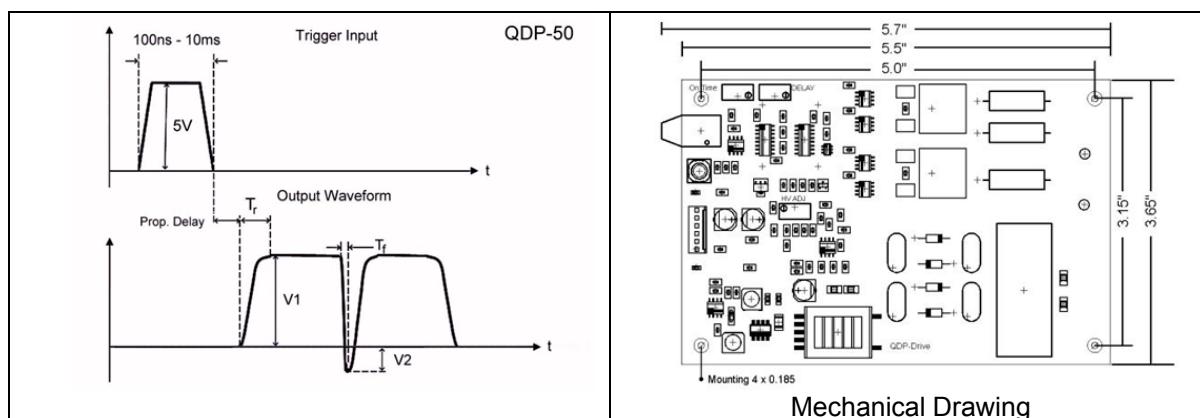
#### **Applications**

- Medical lasers
- Industrial lasers
- Etching/marketing

#### **Specifications**

Parameter	Conditions	Min	Max	Units
<b>OUTPUT PULSE PARAMETERS</b>				
Pulse repetition rate	Same as trigger input	1	50	Hz
Amplitude (V1+V2)	Adjustable (V2 = 10% of V1)	1.2	4.0	kV
Total HV on time	Adjustable or fixed	300	600	µs
Delayed center pulse	Adjustable (range can be modified)	160	200	µs
Rise time	3.5 kV, 6 pF	1	5	µs

Fall time	3.5 kV, 6 pF	< 10	ns	
Load capacitance	With Pockels cell leads	30	pF	
<b>POWER REQUIREMENTS</b>				
Input voltage	Exceeding 20 VDC will damage driver	15	18	VDC
Input current	4.0 kV, 50 Hz, 10pf load	250	mA	
<b>TRIGGER</b>				
Input impedance	Nom. 50 Ω	48	52	ohms
Amplitude	Nom. 5 V	4	10	V
Pulse width	Set by user	100n	10m	sec
Propagation delay	After trailing edge of trigger	80	100	ns
<b>ENVIRONMENTAL</b>				
Ambient air temperature		50	°C	



## 5. STG-HVR OEM Pockels Cell Driver



The OEM driver is designed to switch Pockels cells used for pulse management in high repetition rate ultrafast laser regenerative amplifiers. The HVR drive can drive Pockels cells at  $1/4 \lambda$  or  $1/2 \lambda$  up to 7.5 kV and up to 200 kHz. The driver produces a top-hat waveform with fast rising and falling edges. Heat load and space requirements are at a minimum due to the use of external power supplies and control electronics.

The HVR driver measures 136.5x178x70 mm (5.375x7.0x2.8") with the standard heat sink for convection cooling. It can also be air-cooled or water-cooled for higher repetition rates. We can supply the driver in different form factors for high volume applications. On/Off trigger inputs can be standard TTL signals or optional optical trigger inputs can be supplied.

We can work with you to customize the driver for your specific application. Options such as remote monitoring, remote shutdown and over temperature indicators can be supplied.

### Key Features

- 0 200 kHz repetition rate pulses
- 1.0 7.5 kV output voltage

- 10-15 ns rise and fall times
- 250 ns 3 µs pulse widths
- Bipolar balanced output

### Key Benefits

- Compact footprint
- Reduced heat load
- Easy integration
- Flexible design

### Applications

- Metal cutting
- Welding
- Glass cutting
- Sapphire cutting
- Spectroscopy

### Specifications

Parameter	Conditions	Min	Max	Units
<b>OUTPUT PULSE PARAMETERS</b>				
Repetition rate	7.5 kV, 10 pF, water cooled <sup>2</sup>		100	kHz
	6.0 kV, 10 pF, water cooled		150	kHz
	5.0 kV, 10 pF, water cooled		200	kHz
Duty cycle	Ratio of pulse width to period (1/frequency)		20	%
Pulse amplitude		1.0	7.5	kV
Rise/fall times		10	15	ns
<b>POWER REQUIREMENTS</b>				
Low voltage supply		15.0	18.0	VDC
Low voltage supply	200 kHz rep rate		300	mA
2 x high voltage supplies	For 7.5kV out, external ± 1875 VDC required <sup>1</sup>		100	mA
<b>TRIGGER</b>				
On/Off trigger voltage	Normally 5 V, TTL	4	15	V
Trigger to output delay	5 V trigger		60	ns
Pulse width	(subject to 20% duty cycle maximum)	250	3000	ns
Jitter, trigger to output	2 ns trigger rise time		50	ps
<b>ENVIRONMENTAL</b>				
Operating ambient		0	50	°C

### NOTES

Two external high voltage power supplies are required; one positive output, one negative output.

For example, to achieve 6 kV output you will need ±1500 VDC input.

1. High voltage current requirements are determined by the pulse width and repetition rate. Rise and fall times vary with output voltage; higher voltages produce longer rise and fall times.
2. Convection cooled, the maximum rep rate is 25 kHz @ 7.5 kV, 37.5 kHz @ 6 kV and 50 kHz @ 5 kV. Water cooled, chiller set to 24°C, flow rate to 1.5 gal/minute (6L/min) nominal.

### CAUTIONS

Do not connect the outputs to ground or damage to the driver will occur.

The low voltage supply must be on before applying the high voltage inputs.

The On/Off triggers must not overlap or damage to the driver will occur.

### 6. STG-HVR-SYSTEM Pockels Cell Driver

The HVR-SYSTEM is a turn-key integrated driver and control system to switch Pockels cells used for pulse management in high repetition rate ultrafast laser regenerative amplifiers.

The driver can drive Pockels cells at 1/4λ or 1/2λ up to 7.5kV and up to 200 kHz. The driver produces a top-hat waveform with fast rising and falling edges. The driver operated from any 88-264VAC, 50-60Hz input, it requires only an AC source and a TTL signal to operate. A built-in digital voltmeter allows you to set the output voltage before applying it to the driver and separate high voltage enable/disable buttons

are standard for added safety. A separate trigger on/off switch provides easy pulse control which also disables the high voltage at the rear panel output connectors.



The driver comes in a standard 483mm (19") rack mount enclosure which can also be used as a benchtop unit. It comes with forced air cooling for operation up to 50 kHz or water-cooled for higher repetition rates.

We can work with you to customize the system for your specific application. Option such as optical triggering, remote control and over-temperature indicators can be supplied.

#### **Key Features**

- 0-50 kHz repetition rate (air-cooled)
- 0-200 kHz repetition rate (water-cooled)
- 1.0-7.5 kV output voltage
- 10-15 ns rise and fall times
- 250 ns-3 us pulse widths
- Bipolar balanced output
- Standard 483mm (19") rack mounting
- Dimensions: 432x381x95.25mm (17x15x3.75")

#### **Key Benefits**

- Turn-key driver solution
- Built in digital voltmeter
- Easy integration
- Flexible design

#### **Applications**

- Metal cutting
- Welding
- Glass cutting
- Sapphire cutting
- Spectroscopy

#### **Specifications**

Parameter	Conditions	Min	Max	Units
<b>OUTPUT PULSE PARAMETERS</b>				
Max pulse repetition rate	Air cooled		50	kHz
	Water cooled		200	kHz
Max duty cycle	Ratio if pulse width to period (1/freq)		20	%
Pulse amplitude		1.0	7.5	kV
Rise/fall times	6-10 pF output capacitance <sup>1</sup>	10	15	ns
<b>POWER REQUIREMENTS</b>				
Input voltage		88	264	mA
Input frequency		50	60	Hz
<b>TRIGGER</b>				
Voltage	Normally 5 V, 50 Ω input impedance	4	6	V
Trigger to output delay	5 V trigger		100	ns

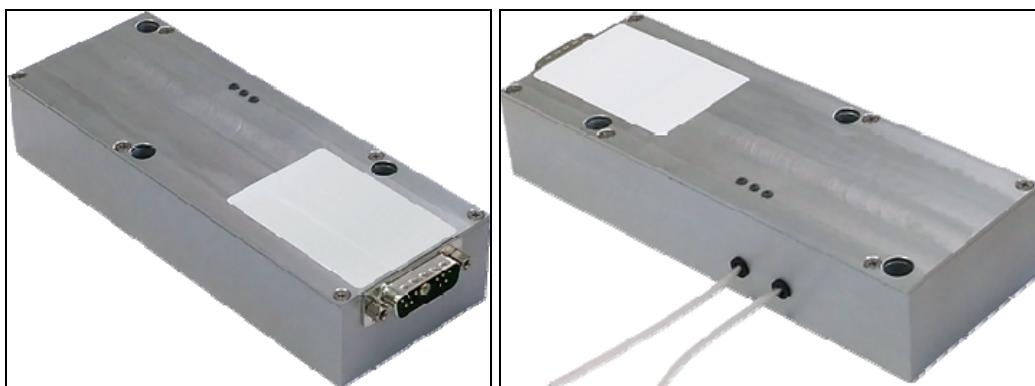
Pulse width	(subject to 20% duty cycle maximum)	250	3000	ns
<b>ENVIRONMENTAL</b>				
Operating ambient		0	40	°C

1 Unit has been tested with up to a 100 pF load and demonstrated rise/fall times less than 40 ns

#### Standard Output Configurations

Amplitude	Maximum rep rate	Model number	Cooling method
0-6 kV	10 kHz	HVR-60010	Air
0-6 kV	30 kHz	HVR-60030	Air
0-6 kV	150 kHz	HVR-60150	Water
0-7.5 kV	5 kHz	HVR-75005	Air
0-7.5 kV	10 kHz (0-6 kV @ 20 kHz)	HVR-75010	Air
0-7.5 kV	100 kHz (0-5 kV @ 20 kHz)	HVR-75100	Water

#### 7. STHVSW03-OEM Drivers



STHVSW03 is a specialized Pockels cell driver that performance is optimized for pico- and femtosecond lasers. Main applications are pulse picking and regenerative amplifier control. Maximal output voltage is 2kV; maximal repetition rate achieves 1MHz at 1.5kV output voltage and 2MHz at <1.0kV output voltage. Transition times are as fast as 5-7ns in dependence on load capacitance and driver's configuration. Pulse width is <15ns (fixed), then 100-2000ns (adjustable by the customer). Interfaces are analogue and RS-485. Configuration software for Windows® 7 is available.

Compact design (about 0.3dm<sup>3</sup>), conductive cooling through the bottom surface and embedded high voltage power supply (i.e. driver's input is +24V DC) are additional benefits.

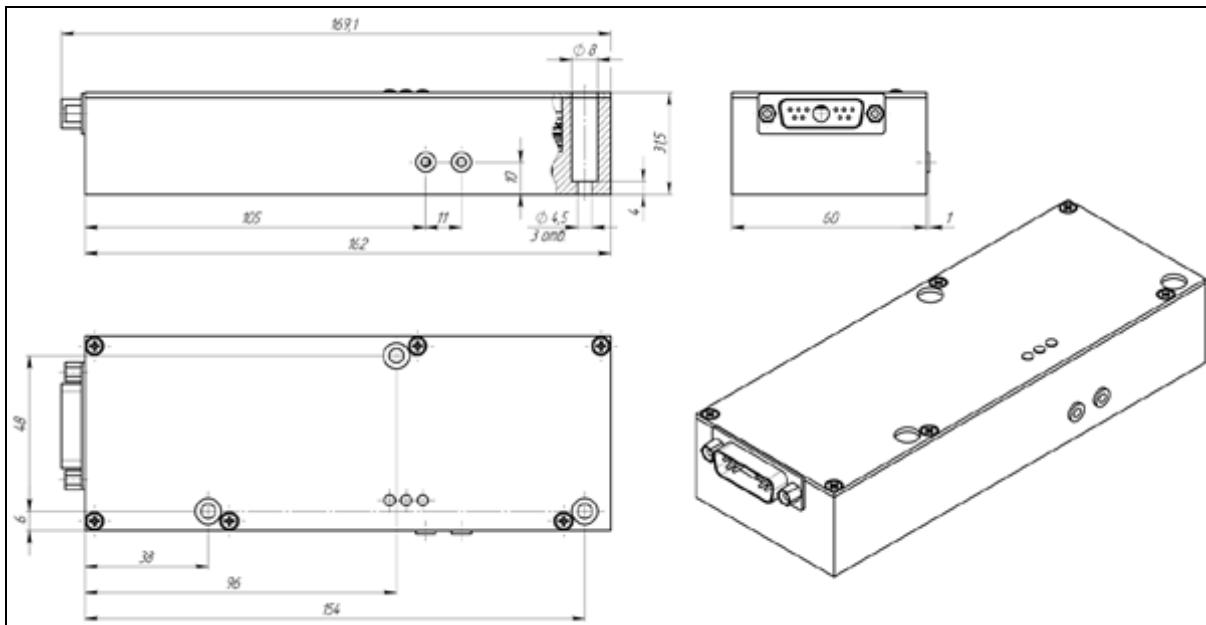
#### Specifications

Input	+24V DC; 5.5A max
Output	Pulses of high voltage and high repetition rate delivered to the capacitive load (e.g. to the Pockels cell)
Output type	Bipolar
Pulse basement <sup>1</sup>	0V, fixed
Pulse amplitude <sup>1,2</sup>	adjustable in 0-2kV range
Maximal repetition rate <sup>2</sup>	Up to 1-2MHz (see also Performance section)
Minimal repetition rate	Single shot (there is an internal re-striking circuit which makes the operations at such a low repetition rate possible)
Pulse width	<ul style="list-style-type: none"> <li>- Fixed, about 15ns in Fixed pulse width mode</li> <li>- 100ns-2000ns adjustable (customizable) in Variable pulse width mode</li> </ul>
Interpulse interval	>100ns
Risetime / falltime <sup>3</sup>	5-7ns
Delay time	<50ns
Jitter	<0.5ns ( $\pm 250$ ps)
Load capacitance	5-7pF typically
Protections	<ul style="list-style-type: none"> <li>- From too long pulses (Gate limit), adjusted by the customer in 200ns to 2200ns range<sup>3</sup></li> <li>- From overheating</li> </ul>
Operation temperature	10 ~ 40°C
Storage temperature	-20 ~ +60 °C
Humidity	90%, non-condensing

Dimension	69x60x32mm
Weight	<0.5kg

- In terms of bipolar output (see also Technical notes section)
- Maximal pulse repetition rate depends on pulse amplitude, pulse amplitude and pulse repetition rate cannot achieve their maximums at the same time
- 10-90% level, warranted at load capacitance 11pF and below
- These and other parameters might be changed upon request.

### Dimension

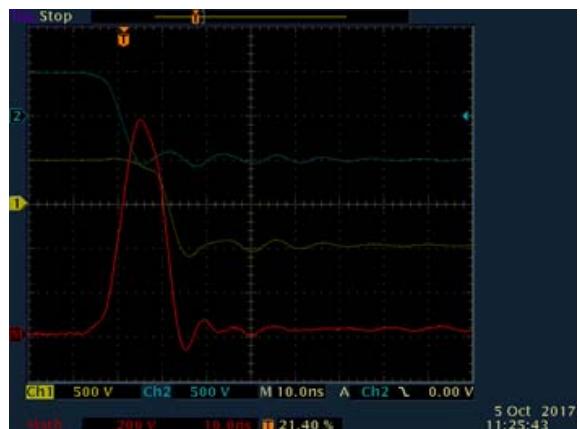


### Performance

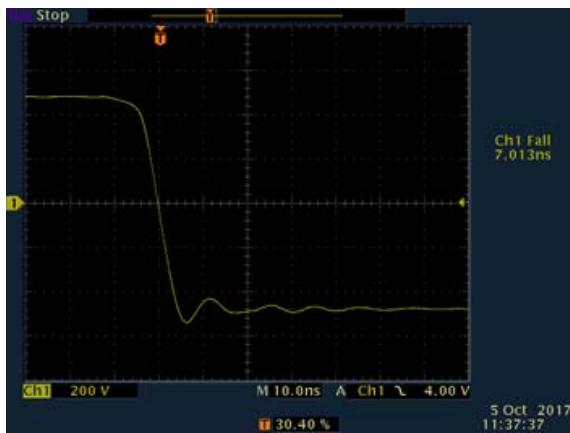
Driver's performance (i.e. the maximal possible repetition rate) depends on load capacitance, pulse amplitude and the performance of cooling system and limited with internal temperature (we do not recommend to exceed 80-90 °C transistor temperature) and the current consumption (we do not recommend to exceed 5A current consumption).



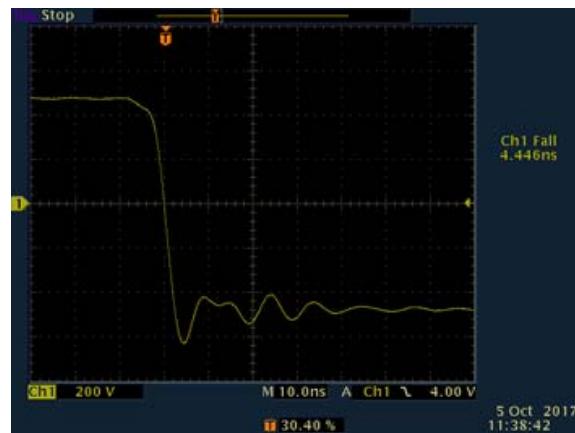
Pulse width mode - variable



Pulse width mode - fixed

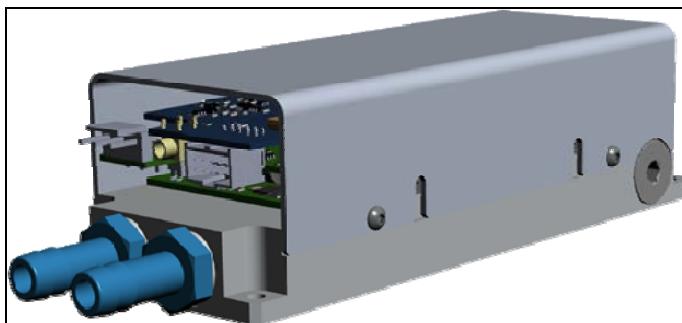


Triggering - soft



Triggering - harsh

## 8. STHVSW04-OEM Drivers



STHVSW-04 is a specialized Pockels cell driver that performance is optimized for pico- and femtosecond lasers. Main applications are pulse picking and regenerative amplifier control. Maximal output voltage is 4kV; maximal repetition rate is 4MHz at approx. 1.6kV output voltage and 1MHz at approx. 3.2kV output voltage. Target performance is as below:

- 1.6kV, 4MHz, <300W power consumption
- 3.2kV, 1MHz, <300W power consumption

Transition times are as fast as 5-7ns in dependence on load capacitance and driver's configuration. Pulse width is <15ns (fixed), then 100-2000ns (adjustable by the customer). For operations the driver needs both HV and LV power. HV DC input should be bi-polar. LV power is 24VDC, <2A. Module is water cooled. Different configurations of water inlets available on request. Interfaces are analogue and RS-485. Configuration software for Windows® 7 is available.

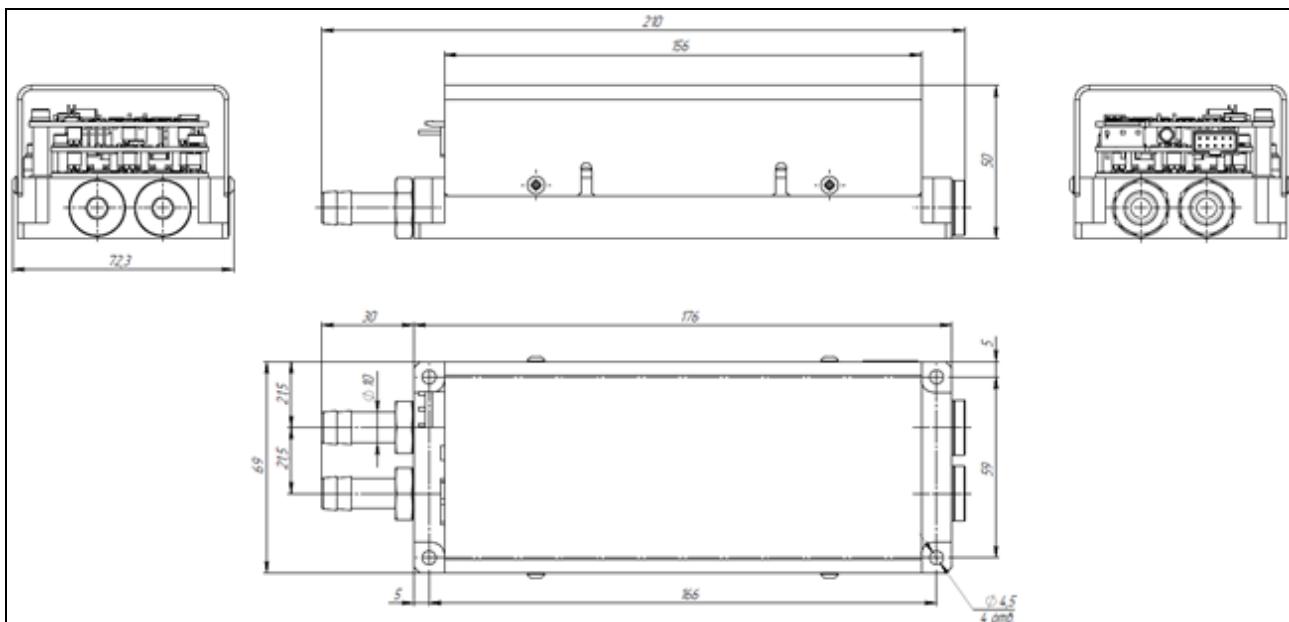
### Specifications

LV input	+24V DC; 1.5A max
HV input	+HV/2 by one wire; -HV/2 by another wire
Output	Pulses of high voltage and high repetition rate delivered to the capacitive load (e.g. to the Pockels cell)
Output type	Bipolar
Pulse basement <sup>1</sup>	0V, fixed
Pulse amplitude <sup>1, 2</sup>	adjustable in 0-4kV range
Maximal repetition rate <sup>2</sup>	Up to 4MHz
Minimal repetition rate	Single shot (there is an internal re-striking circuit which makes the operations at such a low repetition rate possible)
Pulse width	<ul style="list-style-type: none"> <li>– Fixed, about 15ns in Fixed pulse width mode</li> <li>– 100ns-2000ns adjustable (customizable) in Variable pulse width mode</li> </ul>
Interpulse interval	>100ns
Risetime / falltime <sup>3</sup>	5-7ns
Delay time	<50ns
Jitter	<0.5ns ( $\pm 250\text{ps}$ )
Load capacitance	5-7pF typically
Protections	<ul style="list-style-type: none"> <li>– From too long pulses (Gate limit), adjusted by the customer in 200ns to 2200ns range<sup>3</sup></li> <li>– From overheating</li> </ul>

Operation temperature	10 ~ 40°C
Storage temperature	-20 ~ +60 °C
Humidity	90%, non-condensing
Dimension	69x60x32mm
Weight	<0,5kg

- In terms of bipolar output (see also Technical notes section)
- Maximal pulse repetition rate depends on pulse amplitude, pulse amplitude and pulse repetition rate cannot achieve their maximums at the same time
- 10-90% level, warranted at load capacitance 11pF and below
- These and other parameters might be changed upon request

### Dimension



### 9. STQBD Series OEM Driver

STQBD is the series of high repetition rate Pockels cell drivers allowing simple and reliable operation of Q-switched lasers. Devices provide wide range of output direct voltages (up to 6 kV). It allows operation with Pockels cells assembled on different electrooptical crystals from low quarter-wave voltage Lithium Niobate and BBO to DKDP that requires much higher voltage levels for proper operation. QBD-series Pockels Cell Drivers have modifications both for pull-up and pull down schemes.

STQBD-Series devices provide high repetition rates (up to 100 kHz) that makes them a good solution for electro-optical Q-switched lasers with CW pumping. On the other hand a short rising (falling) time allows operation in short pulsed systems with high peak output power and energy (flashlamp-pumped Nd:YAG lasers).

Another advantage is the ability of operation with extremely high loads (up to 0.5 nF). This feature leads to higher reliability of the device and permits remote operation of Pockels cell in laser head that can be connected to driver using long cables (correct and effective operation has been approved with cables up to 3 meters). This allows the designing of Q-switched laser systems with compact remote laser heads where close placement of Pockels cell and driver is impossible because of volume insufficiency or other causes.

#### Features

- Compact OEM design
- Up to 6 kV output voltage
- Long cable operation
- Up to 100 kHz repetition rate
- Up to 0.5 nF load
- Pull-up and pull-down scheme modifications



## Specifications

Input:	
Voltage	+24VDC
Output:	
Working modes	pull-down (= normally on) or push-up (= normally off)
Voltage, high level	regulated, up to 6 kV <sup>1</sup>
Voltage, low level	fixed, 0 V
Repetition rate	up to 50 kHz (CW), up to 100 kHz (burst-mode) <sup>1, 2</sup>
Load	up to 0.5 nF <sup>1</sup>
Rise time (Fall time)	< 20 ns <sup>3</sup>
Recovery time	5-10 us (depends on load)
Jitter	10 ns
Delay time	1 us
Leakage current	not more than 150 uA
Environment:	
Operation temperature	0 ... +40 °C (-40 : +50 °C in HE modification)
Storage temperature	-20 ... +60 °C
Humidity	90 %, non-condensing
Size (LxWxH)	110x80x25 mm
Weight	0.1 kg

<sup>1</sup>These parameters aren't independent and cannot achieve their maximum at the same time...

<sup>2</sup> forced air cooling is required for operating with high repetition rates...

<sup>3</sup> 10-90% level; warranted at load capacitance 23 pF and below...

## Part Number Description:

STQBD-XXYY-ZZ

STQBD – STQBD series EO Q-switch driver

XX – maximum output voltage from 20 to 60 (2 - 6kV)

YY – minimum output voltage from 12 to 20 (1.2 – 2.0kV)

ZZ – UP: modification for pull-up scheme; DN: modification for pull-down scheme

We offer five standard solutions:

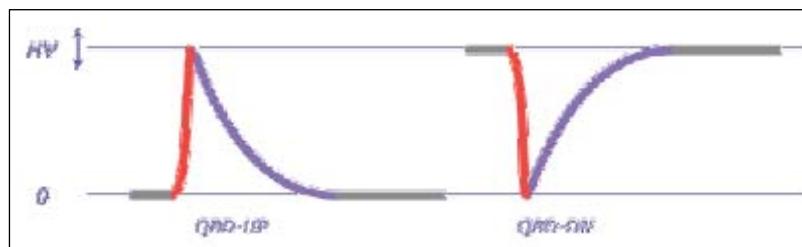
STQBD-6024-UP/DN

STQBD-5020-UP/DN

STQBD-4016-UP/DN

STQBD-3012-UP/DN

STQBD-2008-UP/DN



## Options

Adjustment range of output voltage (see figure) can be selected within the following model series: STQBD-6024 (2.4-6 kV), STQBD-5020 (2-5 kV), STQBD-4016 (1.6-4 kV), STQBD-3012 (1.2-3 kV), STQBD-2008 (0.8- 2 kV).

STQDB-series Pockels cell drivers have two modifications: working by pull-up scheme or working by pull-down scheme.

Most of time gate is retained under voltage that is indicated in grey on figure; time of rapid growth/slump (20 ns) is indicated in red; time of relatively slow recovery (~10 us) is indicated in blue. Adjustable voltage level is designated by the arrow.

## Applications

STQBD-Series Pockels Cell Drivers are available in standard and special versions. Standard modification is a relatively simple OEM device designated for operation in laboratory or medical laser systems at normal temperature and humidity conditions. These modules are designed in accordance with IEC60601-1 medical safety standard requirements. Output parameters (direct high voltage) are controlled by use of analog interface.

Special version is available for laser systems designated for operation in harsh environment. These

devices are distinguished due to wide operation temperature range, humidity and vibration steadiness. In this version all parameters are controlled by simple and reliable internal multi-turn trim pots.

## 10. STQBU Series OEM Drivers

STQBU is a series of multi-functional Pockels cell drivers of hi-end class. In contrast to analogues, they can provide rapid switching of input voltage in two directions: both up and down. STQBU-Series Pockels Cell Driver is extremely flexible solution for driving of the Pockels cell that works upon any user-defined scheme (that may be pull-up, pull-down schemes or any combinations of them).

Modules provide wide range of output direct voltages (up to 5 kV). It allows operation with Pockels cells assembled on different electrooptical crystals from low quarter-wave voltage Lithium Niobate and BBO to DKDP that requires much higher voltage levels for proper operation.

Moreover, STQBU-Series modules provide high repetition rates (up to 100 kHz) that makes them a good solution for electro-optical Q-switched lasers with CW pumping. On the other hand a short rising (falling) time allows operation in short-pulsed systems with high peak output power and energy (flashlamp pumped Nd:YAG lasers).

Another advantage of STQBD-series drivers is an ability of handling with extremely high loads (up to 0.5 nF). This feature leads to higher reliability of the device and permits remote operation of Pockels cell in laser head that can be connected to driver using long cables (correct and effective operation has been approved with cables up to 3 meters). This allows the designing of Q-switched laser systems with compact remote laser heads where close placement of Pockels cell and driver is impossible because of volume insufficiency or other causes.

### **Features**

- Extremely flexible solution
- Pull-up and pull-down schemes
- Up to 5 kV output voltage
- Up to 0.5 nF load
- Compact OEM design
- Long cable operation
- Up to 100 kHz repetition rate

### **Specifications**

Input:	
Voltage	+24VDC
Output:	
Voltage	up to 5 kV
Repetition Rate	from single pulse to 100
Load	up to 0.5 nF
Rise time / Fall time	20 ns
Safety:	
Leakage Current	not more than 150 uA
Environment:	
Operation Temperature	-20...+45 C
Storage Temperature	-40...+85 C
Humidity	90%, non-condensing
Size (LxWxH)	130x80x20 mm
Weight	0.1 kg
Options	Harsh environment version



### **Part Number Description:**

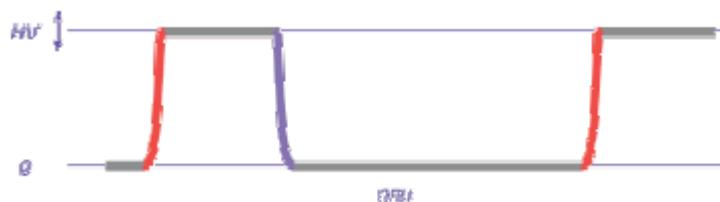
STQBU-XXYY

STQBU – STQBU series EO Q-switch driver

XX – maximum output voltage from 20 to 60 (2 - 6kV)

YY – minimum output voltage from 12 to 20 (1.2 – 2.0kV)

We offer four standard solutions:  
 STQBU-6024  
 STQBU-5020  
 STQBU-4016  
 STQBU-3012  
 STQBU-2008



### Options

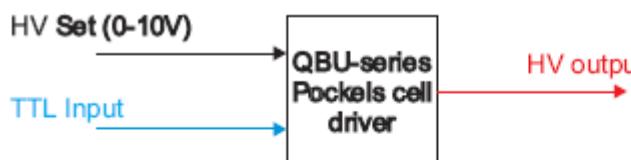
Adjustment range of output voltage (see figure) can be selected within the following model series: STQBU-5020 (2-5 kV), STQBU-4016 (1.6-4 kV), STQBU-3012 (1.2-3 kV), STQBU-2008 (0.8-2 kV). Time of rapid pulse growth (20 ns) is indicated red on figure time of same rapid slump is indicated blue (20 ns). Adjustable voltage level is designated by the arrow.

### Application

STQBU-Series Pockels Cell Drivers are available in standard and special versions. Standard modification is a relatively simple OEM device designated for operation in laboratory or medical laser systems at normal temperature and humidity conditions. These modules are designed in accordance with IEC60601-1 medical safety standard requirements. Output parameters (direct high voltage) are controlled by use of analog interface.

Special version is available for laser systems designated for operation in harsh environment. These devices are distinguished due to wide operation temperature range, humidity and vibration steadiness. In this version all parameters are controlled by simple and reliable internal multi-turn trim pots.

### Working Scheme



TTL input of almost arbitrary shape



HV output follows TTL input with short rise/fall times



## 11. STQBU-BT Series EO Q-switch Drivers

STQBU-BT-series consist of five Pockels cell drivers differ with their output voltage range and covering range up to 6.0 kV. High repetition rates and fast transition times are additional benefits.

Modules allow operations in three different modes (pull down scheme (= normally on), push up scheme (= normally off) and external synchronization mode (= repetition of external low voltage signal)) and therefore suit ideally for the laboratory usage.

### Features

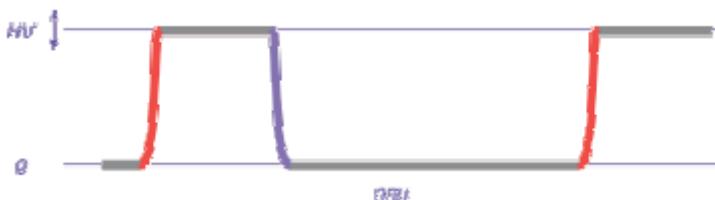
- Extremely flexible solution
- Push-up and pull-down schemes
- Up to 6 kV output voltage
- Up to 50 kHz (CW) repetition rate
- Pulses width from 1us to DC
- 20 ns rise/fall times
- RS-232 interface



### Specifications:

Input:	
Voltage	110/230 VAC; 50/60 Hz

Current	1 A max
Output:	
Working modes	Pull-down scheme, push-up scheme, repetition of external signal
Voltage, high level	regulated, up to 6 kV
Voltage, low level	fixed, 0 V
Pulse width	1 us - DC
Repetition rate	up to 50 kHz (CW), up to 100 kHz (burst-mode)
Rise time	< 20 ns
Fall time	< 20 ns
Jitter	10 ns (1 ns in LJ-modification)
Delay time	1 us (100 ns in LJ-modification)
Load capacitance	up to 0.5 nF
Environment:	
Operation temperature	0 ... +40 °C
Storage temperature	-20 ... +60 °C
Humidity	90 %, non-condensing
Size (LxWxH)	225x200x60 mm
Weight	2 kg



### Performance

For STQBU-BT-5020 continuously operated in internal synchronization mode we warrant the performance table as follows:

11 pF load capacitance							
Voltage, kV	2.0	2.5	3.0	3.5	4.0	4.5	5.0
Max. rep. rate, kHz	56	40	31	24	18	15	12
23 pF load capacitance							
Voltage, kV	2.0	2.5	3.0	3.5	4.0	4.5	5.0
Max. rep. rate, kHz	45	32	24	18	14	12	9

External synchronization mode shows usually a little higher performance.

In the burst-mode (= short time operations) performance is increasing approximately twice and may achieve 100 kHz value at low operating voltages and load capacitance.

High load capacitance decreases the performance.

### Part Number Description:

STQBU-BT-XXYY

STQBU-BT – STQBU-BT series EO Q-switch driver

XX – maximum output voltage from 20 to 60 (2 - 6kV)

YY – minimum output voltage from 12 to 20 (1.2 – 2.0kV)

We offer five standard solutions:

STQBU-BT-6024

STQBU-BT-5020

STQBU-BT-4016

STQBU-BT-3012

STQBU-BT-2008



### Options

Adjustment range of output voltage can be selected within the following model series: STQBU-BT-6024 (2.4-6 kV), STQBU-BT-5020 (2-5 kV), STQBU-BT-4016 (1.6-4 kV), STQBU-BT-3012 (1.2-3 kV), STQBU-BT-2008 (0.8- 2 kV).

## Pockels Cell (EO Q-switch) Questionnaire

If you would like us to make a Pockels cell recommendation, we would like to know the following information about your application:

- Information needed for any Pockels cell inquiry

1 What is the application of this pockels cell (Q-switch, regenerative amplifier, pulse picker or other)?

Ans :

2 What is the beam diameter or radius (1/e2 value)? Please specify as Radius of Diameter.

Ans :

3 What is the beam profile (Guassian, Pseudo-Gaussian, Top-hat, etc)?

Ans :

4 What is the wavelength of operation (nm)?

Ans :

5 What is the laser repetition rate?

Ans :

6 What is the laser peak power (extra-cavity)?

Ans :

7 What is the energy-per-pulse?

Ans :

8 What is the pulse width (FWHM)?

Ans :

9 Will you use the cell in quarter-wave or half-wave operation?

Ans :

10 What is the cell repetition rate and voltage pulse duration that you intend to use?

Ans :

11 What is your duty cycle?

Ans :

12 What is the operating environment at the cell (temp, atmosphere, humidity)?

Ans :

13 If using a laser cavity, what is the finesse or output coupler reflectivity?

Ans :

14 Do you intend to use a bias or constant on voltage, switching to ground? (This is not typically recommended and may cause short cell life)

Ans :

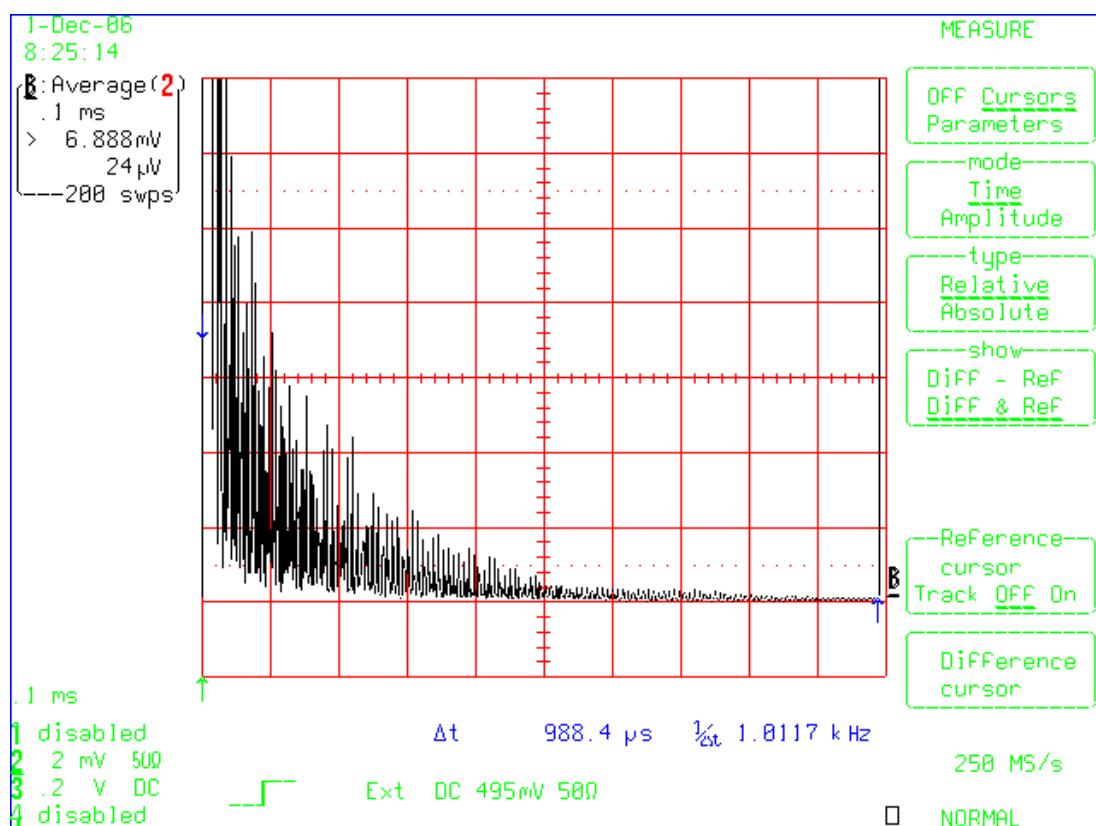
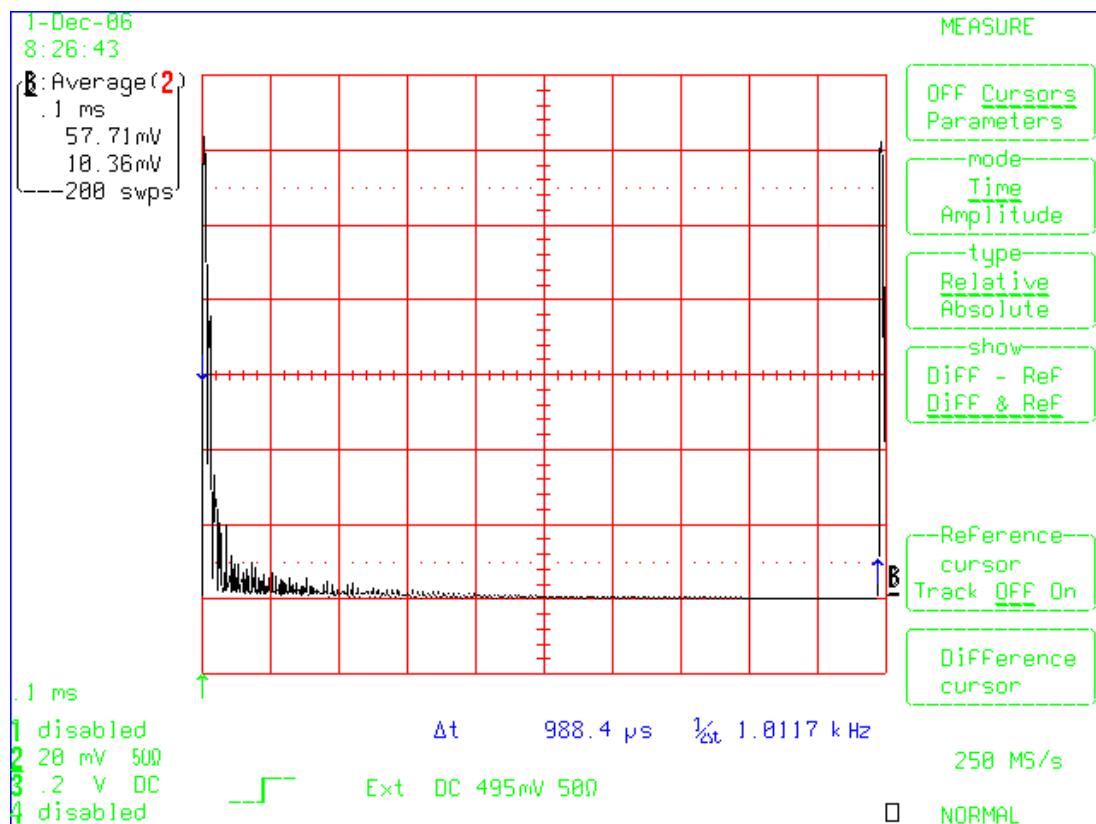
15 What quantity do you require?

Ans :

### 1. How to Select an EO Q-switch to Meet Your Switching Frequency Requirement

The simple answer is that the IMPACT Pockels cells are recommended for operation at a maximum of 1-2kHz. This is not to say they will completely fail to operate at 5kHz. The contrast ratio will be sacrificed as the repetition rate is increased beyond 1kHz. The reason for this is contained within the nature of the DKDP crystal. When high voltage is applied, the crystal lattice is distorted, causing the desired Pockels effect. However, the longer that the voltage is applied, either in terms of electric pulse duration or in the repetition rate used, the distortion causes an acoustic resonance to develop. This is commonly referred to as "ringing" in the crystal. This is true of any cell that uses KDP/DKDP as its crystal element. To illustrate this point, the following figures show several optical traces of the acoustic ringing

from an IMPACT 8 Pockels cell when operated at 1kHz repetition rate. One trace ( time stamp 8:26:43) allows the vertical (y-axis) to autoscale to a maximum of the signal from the electrical pulse. In the second trace ( time stamp 8:25:14), we have collapsed the y-axis so that you don't see the maximum of the electrical pulse. Although the collapsed y-axis truncates the initial pulse maximum, it increases the visual appearance of the acoustic ringing following the initial pulse. In either case, you can see the acoustic ringing subsides after about 1millisec.



Although we generally recommend QX series Pockels cells for applications at >2KHz, whether or not the IMPACT 8 will work depends upon how much loss of contrast ratio their system can tolerate. But if

you want a cut and dry answer, I'd recommend against operation at 5kHz. The QX and IMPACT cells use the same high quality DKDP crystal in similar sizes. The significant difference is the construction of the cell housing. The QX cell design is such that it provides some suppression of this ringing out to about 5KHz normally and is available in a damped version which will suppress this condition to <10KHz.

The BBO cell will operate into the 500KHz region and higher.

## 2. How to Select Aperture

In a Gaussian beam there will be ~10% of the laser energy present at a diameter of 2-3 times the  $1/e^2$  diameter. This will result in a significant loss of energy in the system and this energy can scatter inside of the cell and damage the cell. We would suggest that the aperture of the Q-switch is 2 to 3 times of laser beam diameter ( $1/e^2$ ). If the beam can be modified into something close to a "tophat" profile then the aperture requirement drops substantially.

## 3. What is maximum allowed laser energy? what is the maximum allowed peak power? What is the maximum peak power beam which can be switched off?

If you have a large, perfect beam you can get much more energy through the cell without damage than if you have a beam with hot spots and caustic retro-reflections, etc. In an 8.5mm beam, "typical" maximum wattages would range from 5-30W but, theoretically, DKDP can be used into the 50-75W region...but EVERYTHING has to be perfect. This is one of those situations where general rules just don't have much use.

## 4. What is the laser beam pulse width and rise time?

The performance of the cell is directly related to the driver. The cell has a theoretical rise time on the order of 80ps...but the best drivers can only drive a rise time of 2-6ns. Pulse width and fall time are similarly affected. The electronics are fairly simple for a q-switch driver at 1/4 wave and a few Hz. Driver designs get MUCH more complicated for a region or a pulse picker at 10 or 100KHz and 1/2 wave voltage.

## 5. Do we need a waveplate?

Our cell does not contain a waveplate in it. If the customer's application requires a 1/4 waveplate then he will have to add it into the system himself.

## 6. How to Select a Driver?

Any driver that produces ~3KV (2.6KV) will operate the cell to 1/4 wave. The driver that we offer at [http://www.sintecoptronics.com/qswi\\_tcheoDriver.htm](http://www.sintecoptronics.com/qswi_tcheoDriver.htm) should work.

## 7. How to Select Pulse Shape and Duty Cycle?

You can operate the cell with either a pull-up voltage or a pull-down voltage. Changing the polarity will only change the direction of the phase rotation. You should not, however, operate the cell with a constant applied voltage potential between the terminals, or a duty cycle greater than ~ 2%. "Pull-down" usually involves a constant applied or bias voltage. This type of operation is specifically not recommended. We have had customers that use this method to varying degrees of success. This type of operation usually results in dramatically reduced cell lifetimes. We offer no warranty coverage on cells that have been used in this manner.

## 8. How about Operation Environment?

Our recommended range would be in the 10-30 deg C range. Higher temps will seriously degrade performance. Voltage requirements will change with temperature as well. Also important is the rate of temperature increase. KDP is quite sensitive to thermal shock KD\*P cells should never be warmed or cooled at a rate of more than 1-2 deg per hour.

## 9. How to Place an order for a QX cell?

Fluid filled cells are provided for legacy systems or special applications only. SolGel dry type cells are recommended for optimal performance in most systems. When you place the order for a QX cell, please define window wedge (0 deg or 1 deg) and endcap style (DT, TK, TN).